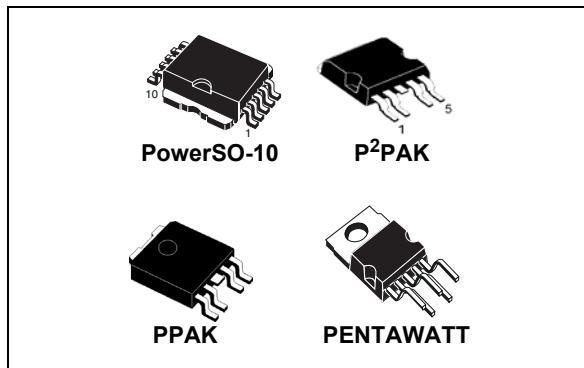


## High-side driver

### Features

Type	$R_{DS(on)}$	$I_{OUT}$	$V_{CC}$
VN820			
VN820SP	40 mΩ		
VN820-B5			
VN820PT			

- Very low standby current
- CMOS compatible input
- On-state open-load detection
- Off-state open-load detection
- Thermal shutdown protection and diagnosis
- Undervoltage shutdown
- Overvoltage clamp
- Output stuck to  $V_{CC}$  detection
- Load current limitation
- Reverse battery protection (see [Figure 24: Application schematic](#))
- Electrostatic discharge protection



### Description

The VN820 is a monolithic device designed in STMicroelectronic's VIPower M0-3 technology. The VN820 is intended for driving any type of load with one side connected to ground. The active  $V_{CC}$  pin voltage clamp protects the device against low energy spikes (see ISO7637 transient compatibility table).

Active current limitation combined with thermal shutdown and automatic restart protects the device against over-load. The device detects the open load condition in both the on and off-state. In the off-state the device detects if the output is shorted to  $V_{CC}$ . The device automatically turns off in the case where the ground pin becomes disconnected.

**Table 1. Device summary**

Package	Order codes	
	Tube	Tape and reel
PENTAWATT	VN820	-
PowerSO-10	VN820SP	VN820SP13TR
P2PAK	VN820-B5	VN820-B513TR
PPAK	VN820PT	VN820PT13TR

## Contents

<b>1</b>	<b>Block diagram and pin description</b>	<b>7</b>
<b>2</b>	<b>Electrical specifications</b>	<b>8</b>
2.1	Absolute maximum ratings	8
2.2	Thermal data	9
2.3	Electrical characteristics	10
2.4	Electrical characteristics curves	15
<b>3</b>	<b>Application information</b>	<b>18</b>
3.1	GND protection network against reverse battery	18
3.1.1	Solution 1: resistor in the ground line (RGND only)	18
3.1.2	Solution 2: diode (DGND) in the ground line	19
3.2	Load dump protection	19
3.3	MCU I/Os protection	19
3.4	Open load detection in off-state	19
3.5	PowerSO-10, P <sup>2</sup> PAK, PPAK, PENTAWATT maximum demagnetization energy (VCC = 13.5V)	21
<b>4</b>	<b>Package and PCB thermal data</b>	<b>22</b>
4.1	P <sup>2</sup> PAK thermal data	22
4.2	PPAK thermal data	24
4.3	PowerSO-10 thermal data	27
<b>5</b>	<b>Package and packing information</b>	<b>30</b>
5.1	ECOPACK®	30
5.2	PENTAWATT mechanical data	30
5.3	P <sup>2</sup> PAK mechanical data	32
5.4	PPAK mechanical data	34
5.5	PowerSO-10 mechanical data	35
5.6	PENTAWATT packing information	37
5.7	P <sup>2</sup> PAK packing information	37
5.8	PPAK packing information	38

5.9	PowerSO-10 packing information . . . . .	40
<b>6</b>	<b>Revision history</b> . . . . .	<b>41</b>

## List of tables

Table 1.	Device summary . . . . .	1
Table 2.	Suggested connections for unused and not connected pins . . . . .	7
Table 3.	Absolute maximum ratings . . . . .	8
Table 4.	Thermal data . . . . .	9
Table 5.	Power . . . . .	10
Table 6.	Switching ( $V_{CC}=13V$ ) . . . . .	10
Table 7.	Input pin . . . . .	11
Table 8.	$V_{CC}$ output diode . . . . .	11
Table 9.	Status pin . . . . .	11
Table 10.	Protections . . . . .	11
Table 11.	Open-load detection . . . . .	12
Table 12.	Truth table . . . . .	13
Table 13.	Electrical transient requirements . . . . .	13
Table 14.	Thermal parameter . . . . .	24
Table 15.	Thermal parameter . . . . .	26
Table 16.	Thermal parameters . . . . .	29
Table 17.	PENTAWATT mechanical data . . . . .	31
Table 18.	P <sup>2</sup> PAK mechanical data . . . . .	33
Table 19.	PPAK mechanical data . . . . .	34
Table 20.	PowerSO-10 mechanical data . . . . .	36
Table 21.	Document revision history . . . . .	41

## List of figures

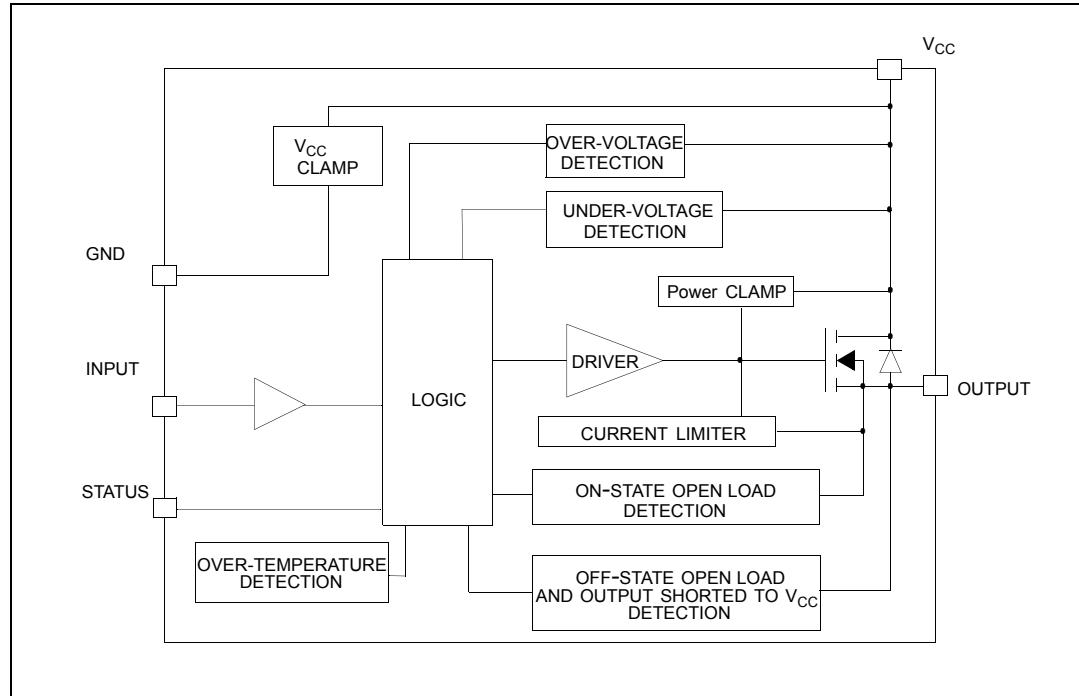
Figure 1.	Block diagram . . . . .	7
Figure 2.	Configuration diagram (top view) . . . . .	7
Figure 3.	Current and voltage conventions . . . . .	8
Figure 4.	Status timings . . . . .	12
Figure 5.	Switching time waveforms . . . . .	12
Figure 6.	Waveforms . . . . .	14
Figure 7.	Off-state output current . . . . .	15
Figure 8.	High level input current . . . . .	15
Figure 9.	Input clamp voltage . . . . .	15
Figure 10.	Status leakage current . . . . .	15
Figure 11.	Status low output voltage . . . . .	15
Figure 12.	Status clamp voltage . . . . .	15
Figure 13.	On-state resistance Vs $T_{case}$ . . . . .	16
Figure 14.	On-state resistance Vs $V_{CC}$ . . . . .	16
Figure 15.	Open load on-state detection threshold . . . . .	16
Figure 16.	Input high level . . . . .	16
Figure 17.	Input low level . . . . .	16
Figure 18.	Input hysteresis voltage . . . . .	16
Figure 19.	Over-voltage shutdown . . . . .	17
Figure 20.	Open load off-state voltage detection threshold . . . . .	17
Figure 21.	Turn-on voltage slope . . . . .	17
Figure 22.	Turn-off voltage slope . . . . .	17
Figure 23.	$I_{lim}$ Vs $T_{case}$ . . . . .	17
Figure 24.	Application schematic . . . . .	18
Figure 25.	Open load detection in off-state . . . . .	20
Figure 26.	PowerSO-10, P <sup>2</sup> PAK, PPAK, PENTAWATT maximum turn-off current versus inductance . . . . .	21
Figure 27.	PC board . . . . .	22
Figure 28.	R <sub>thj-amb</sub> vs PCB copper area in open box free air condition . . . . .	22
Figure 29.	P <sup>2</sup> PAK thermal impedance junction ambient single pulse . . . . .	23
Figure 30.	Thermal fitting model of a single channel . . . . .	23
Figure 31.	PC board . . . . .	24
Figure 32.	R <sub>thj-amb</sub> vs PCB copper area in open box free air condition . . . . .	25
Figure 33.	PPAK thermal impedance junction ambient single pulse . . . . .	25
Figure 34.	Thermal fitting model of a single channel . . . . .	26
Figure 35.	PowerSO-10 PC board . . . . .	27
Figure 36.	R <sub>thj-amb</sub> vs PCB copper area in open box free air condition . . . . .	27
Figure 37.	Thermal impedance junction ambient single pulse . . . . .	28
Figure 38.	Thermal fitting model of a single channel HSD in PowerSO-10 . . . . .	28
Figure 39.	PENTAWATT package dimensions . . . . .	30
Figure 40.	P <sup>2</sup> PAK package dimensions . . . . .	32
Figure 41.	PPAK package dimensions . . . . .	34
Figure 42.	PowerSO-10 package dimensions . . . . .	35
Figure 43.	PENTAWATT tube shipment (no suffix) . . . . .	37
Figure 44.	P <sup>2</sup> PAK tube shipment (no suffix) . . . . .	37
Figure 45.	P <sup>2</sup> PAK tape and reel (suffix "13TR") . . . . .	38
Figure 46.	PPAK suggested pad layout . . . . .	38
Figure 47.	PPAK tube shipment (no suffix) . . . . .	39

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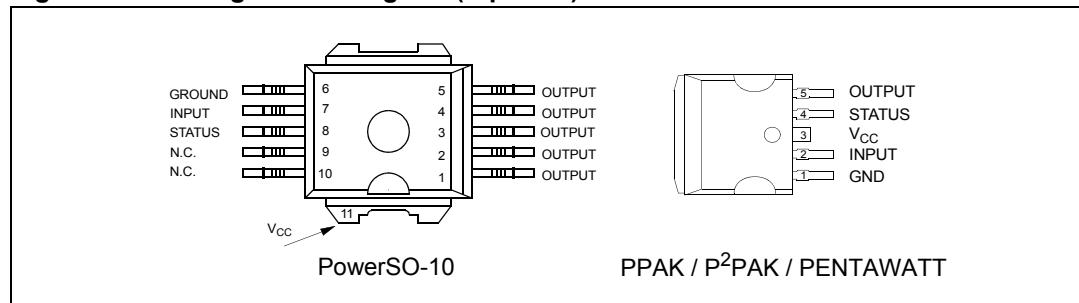
Figure 48. PPAK tape and reel (suffix “13TR”)	39
Figure 49. PowerSO-10 suggested pad layout	40
Figure 50. PowerSO-10 tube shipment (no suffix)	40
Figure 51. PowerSO-10 tape and reel shipment (suffix “TR”)	40

# 1 Block diagram and pin description

**Figure 1. Block diagram**



**Figure 2. Configuration diagram (top view)**

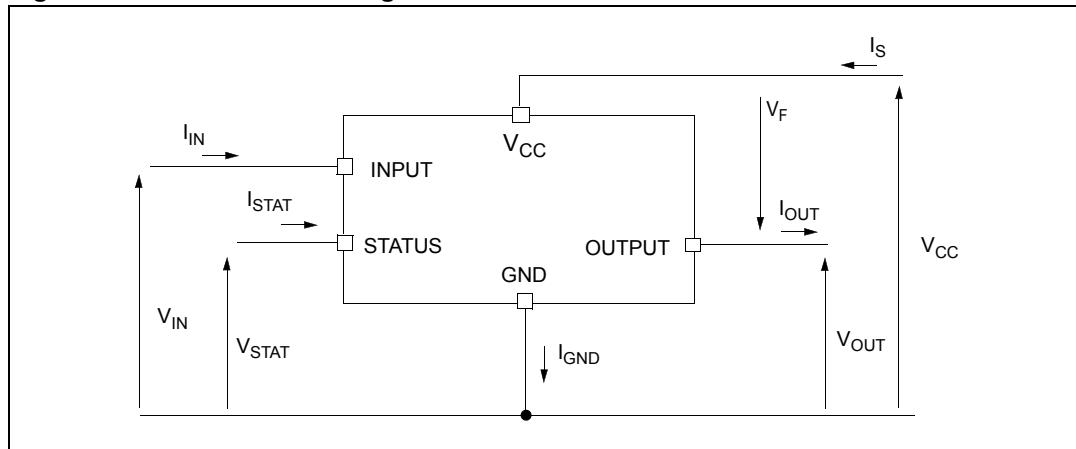


**Table 2. Suggested connections for unused and not connected pins**

Connection / pin	Status	N.C.	Output	Input
Floating	X	X	X	X
To ground		X		Through 10KΩ resistor

## 2 Electrical specifications

**Figure 3. Current and voltage conventions**



### 2.1 Absolute maximum ratings

Stressing the device above the rating listed in the [Table 3](#) may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to Absolute maximum rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics sure program and other relevant quality document.

**Table 3. Absolute maximum ratings**

Symbol	Parameter	Value				Unit
		PowerSO-10	PENTAWATT	P <sup>2</sup> PAK	PPAK	
$V_{CC}$	DC supply voltage	41				V
- $V_{CC}$	Reverse DC supply voltage	- 0.3				V
- $I_{gnd}$	DC reverse ground pin current	- 200				mA
$I_{OUT}$	DC output current	Internally limited				A
- $I_{OUT}$	Reverse DC output current	- 9				A
$I_{IN}$	DC input current	+/- 10				mA
$I_{STAT}$	DC Status current	+/- 10				mA
$V_{ESD}$	Electrostatic discharge (human body model: $R = 1.5 \text{ k}\Omega$ ; $C = 100 \text{ pF}$ )					
	- INPUT	4000				V
	- STATUS	4000				V
	- OUTPUT	5000				V
	- $V_{CC}$	5000				V

**Table 3. Absolute maximum ratings (continued)**

Symbol	Parameter	Value				Unit
		PowerSO-10	PENTAWATT	P <sup>2</sup> PAK	PPAK	
E <sub>MAX</sub>	Maximum switching energy (L = 1.4 mH; R <sub>L</sub> = 0 Ω; V <sub>bat</sub> = 13.5 V; T <sub>jstart</sub> = 150 °C; I <sub>L</sub> = 13 A)		156			mJ
P <sub>tot</sub>	Power dissipation T <sub>C</sub> = 25 °C		65.8			W
T <sub>j</sub>	Junction operating temperature		Internally limited			°C
T <sub>c</sub>	Case operating temperature		- 40 to 150			°C
T <sub>stg</sub>	Storage temperature		- 55 to 150			°C

## 2.2 Thermal data

**Table 4. Thermal data**

Symbol	Parameter	Max. value				Unit
		PowerSO-10	PENTAWATT	P <sup>2</sup> PAK	PPAK	
R <sub>thj-case</sub>	Thermal resistance junction-case	1.9	1.9	1.9	1.9	°C/W
R <sub>thj-amb</sub>	Thermal resistance junction-ambient	51.9 <sup>(1)</sup>	61.9 <sup>(2)</sup>	51.9 <sup>(2)</sup>	76.9 <sup>(2)</sup>	°C/W
		37 <sup>(2)</sup>	-	37 <sup>(4)</sup>	45 <sup>(4)</sup>	°C/W

1. When mounted on a standard single-sided FR-4 board with 0.5 cm<sup>2</sup> of Cu (at least 35 μm thick).

2. When mounted on a standard single-sided FR-4 board with 6 cm<sup>2</sup> of Cu (at least 35 μm thick).

## 2.3 Electrical characteristics

Values specified in this section are for  $8 \text{ V} < V_{CC} < 36 \text{ V}$ ;  $-40^\circ\text{C} < T_j < 150^\circ\text{C}$ , unless otherwise stated.

**Table 5. Power**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{CC}$	Operating supply voltage		5.5	13	36	V
$V_{USD}$	Under-voltage shutdown		3	4	5.5	V
$V_{USDhyst}$	Under-voltage shutdown hysteresis			0.5		V
$V_{OV}$	Over-voltage shutdown		36			V
$R_{ON}$	On-state resistance	$I_{OUT} = 3 \text{ A}; T_j = 25^\circ\text{C}; V_{CC} > 8 \text{ V}$ $I_{OUT} = 3 \text{ A}; V_{CC} > 8 \text{ V}$			40 80	$\text{m}\Omega$ $\text{m}\Omega$
$I_S$	Supply current	Off-state; $V_{CC} = 13 \text{ V}$ ; $V_{IN} = V_{OUT} = 0 \text{ V}$		10	25	$\mu\text{A}$
		Off-state; $V_{CC} = 13 \text{ V}$ ; $V_{IN} = V_{OUT} = 0 \text{ V}; T_j = 25^\circ\text{C}$		10	20	$\mu\text{A}$
		On-state; $V_{CC} = 13 \text{ V}; V_{IN} = 5 \text{ V}$ ; $I_{OUT} = 0 \text{ A}$		2	3.5	mA
$I_{L(off1)}$	Off-state output current	$V_{IN} = V_{OUT} = 0 \text{ V}$	0		50	$\mu\text{A}$
$I_{L(off2)}$	Off-state output current	$V_{IN} = 0 \text{ V}; V_{OUT} = 3.5 \text{ V}$	-75		0	$\mu\text{A}$
$I_{L(off3)}$	Off-state output current	$V_{IN} = V_{OUT} = 0 \text{ V}; V_{CC} = 13 \text{ V}$ ; $T_j = 125^\circ\text{C}$			5	$\mu\text{A}$
$I_{L(off4)}$	Off-state output current	$V_{IN} = V_{OUT} = 0 \text{ V}; V_{CC} = 13 \text{ V}$ ; $T_j = 25^\circ\text{C}$			3	$\mu\text{A}$

**Table 6. Switching ( $V_{CC}=13\text{V}$ )**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$t_{d(on)}$	Turn-on delay time	$R_L = 4.3 \Omega$ from $V_{IN}$ rising edge to $V_{OUT} = 1.3 \text{ V}$		30		$\mu\text{s}$
$t_{d(off)}$	Turn-off delay time	$R_L = 4.3 \Omega$ from $V_{IN}$ falling edge to $V_{OUT} = 11.7 \text{ V}$		30		$\mu\text{s}$
$dV_{OUT}/dt_{(on)}$	Turn-on voltage slope	$R_L = 4.3 \Omega$ from $V_{OUT} = 1.3 \text{ V}$ to $V_{OUT} = 10.4 \text{ V}$	See <a href="#">Figure 21</a>			$\text{V}/\mu\text{s}$
$dV_{OUT}/dt_{(off)}$	Turn-off voltage slope	$R_L = 4.3 \Omega$ from $V_{OUT} = 11.7 \text{ V}$ to $V_{OUT} = 1.3 \text{ V}$	See <a href="#">Figure 22</a>			$\text{V}/\mu\text{s}$

**Table 7. Input pin**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{IL}$	Input low level				1.25	V
$I_{IL}$	Low level input current	$V_{IN} = 1.25 \text{ V}$	1			$\mu\text{A}$
$V_{IH}$	Input high level		3.25			V
$I_{IH}$	High level input current	$V_{IN} = 3.25 \text{ V}$			10	$\mu\text{A}$
$V_{hyst}$	Input hysteresis voltage		0.5			V
$V_{ICL}$	Input clamp voltage	$I_{IN} = 1 \text{ mA}$ $I_{IN} = -1 \text{ mA}$	6	6.8 - 0.7	8	V V

**Table 8.  $V_{CC}$  output diode**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_F$	Forward on voltage	$-I_{OUT} = 2 \text{ A}; T_j = 150^\circ\text{C}$			0.6	V

**Table 9. Status pin**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{STAT}$	Status low output voltage	$I_{STAT} = 1.6 \text{ mA}$			0.5	V
$I_{LSTAT}$	Status leakage current	Normal operation; $V_{STAT} = 5 \text{ V}$			10	$\mu\text{A}$
$C_{STAT}$	Status pin input capacitance	Normal operation; $V_{STAT} = 5 \text{ V}$			100	pF
$V_{SCL}$	Status clamp voltage	$I_{STAT} = 1 \text{ mA}$ $I_{STAT} = -1 \text{ mA}$	6	6.8 - 0.7	8	V V

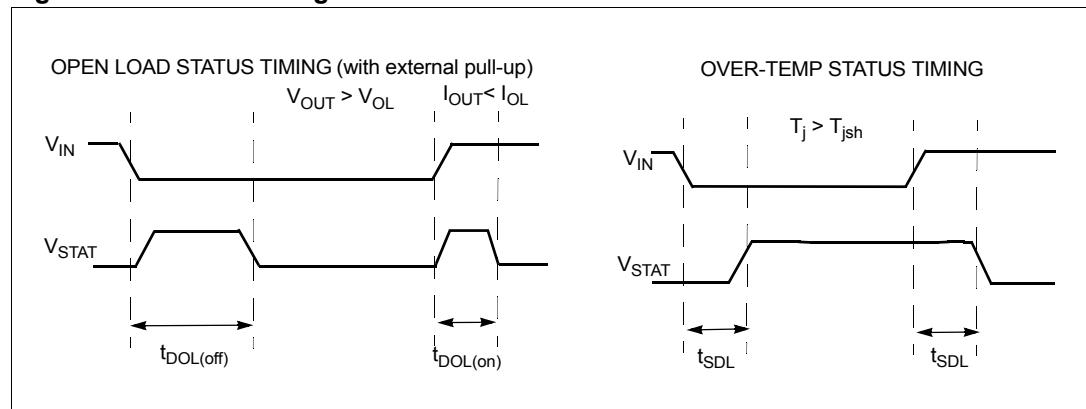
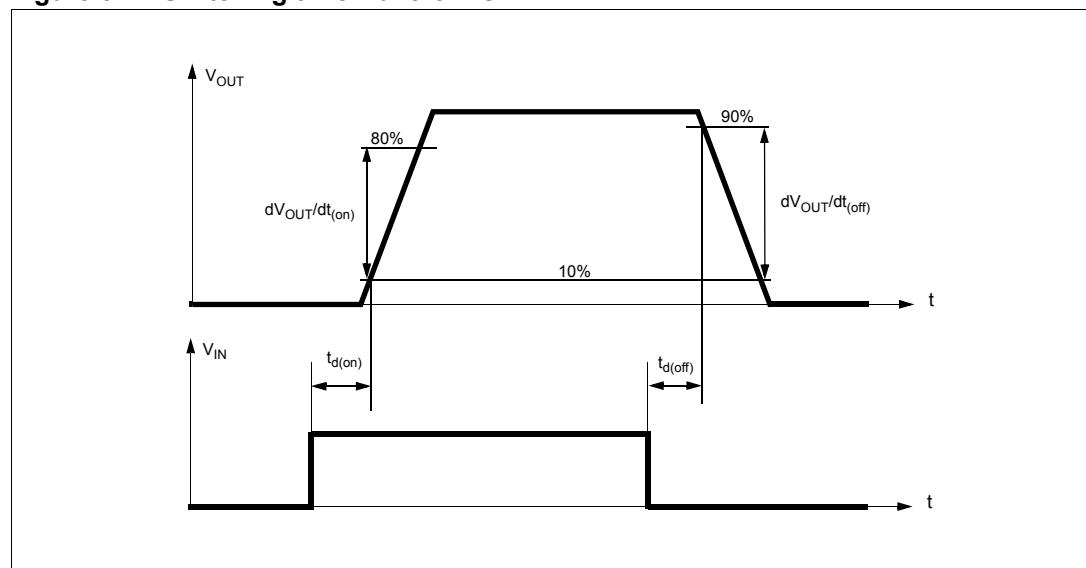
**Table 10. Protections<sup>(1)</sup>**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$T_{TSD}$	Shutdown temperature		150	175	200	$^\circ\text{C}$
$T_R$	Reset temperature		135			$^\circ\text{C}$
$T_{hyst}$	Thermal hysteresis		7	15		$^\circ\text{C}$
$t_{SDL}$	Status delay in over-load condition	$T_j > T_{jsh}$			20	ms
$I_{lim}$	Current limitation	$9 \text{ V} < V_{CC} < 36 \text{ V}$ $5.5 \text{ V} < V_{CC} < 36 \text{ V}$	9	13	20 20	A A
$V_{demag}$	Turn-off output clamp voltage	$I_{OUT} = 3 \text{ A};$ $V_{IN} = 0 \text{ V};$ $L = 6 \text{ mH}$	$V_{CC} - 41$	$V_{CC} - 48$	$V_{CC} - 55$	V

1. To ensure long term reliability under heavy over-load or short circuit conditions, protection and related diagnostic signals must be used together with a proper software strategy. If the device operates under abnormal conditions this software must limit the duration and number of activation cycles.

**Table 11. Open-load detection**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$I_{OL}$	Open-load on-state detection threshold	$V_{IN} = 5V$	70	150	300	mA
$t_{DOL(on)}$	Open-load on-state detection delay	$I_{OUT} = 0A$			200	$\mu s$
$V_{OL}$	Open-load off-state voltage detection threshold	$V_{IN} = 0V$	1.5	2.5	3.5	V
$t_{DOL(off)}$	Open-load detection delay at turn-off				1000	$\mu s$

**Figure 4. Status timings****Figure 5. Switching time waveforms**

**Table 12. Truth table**

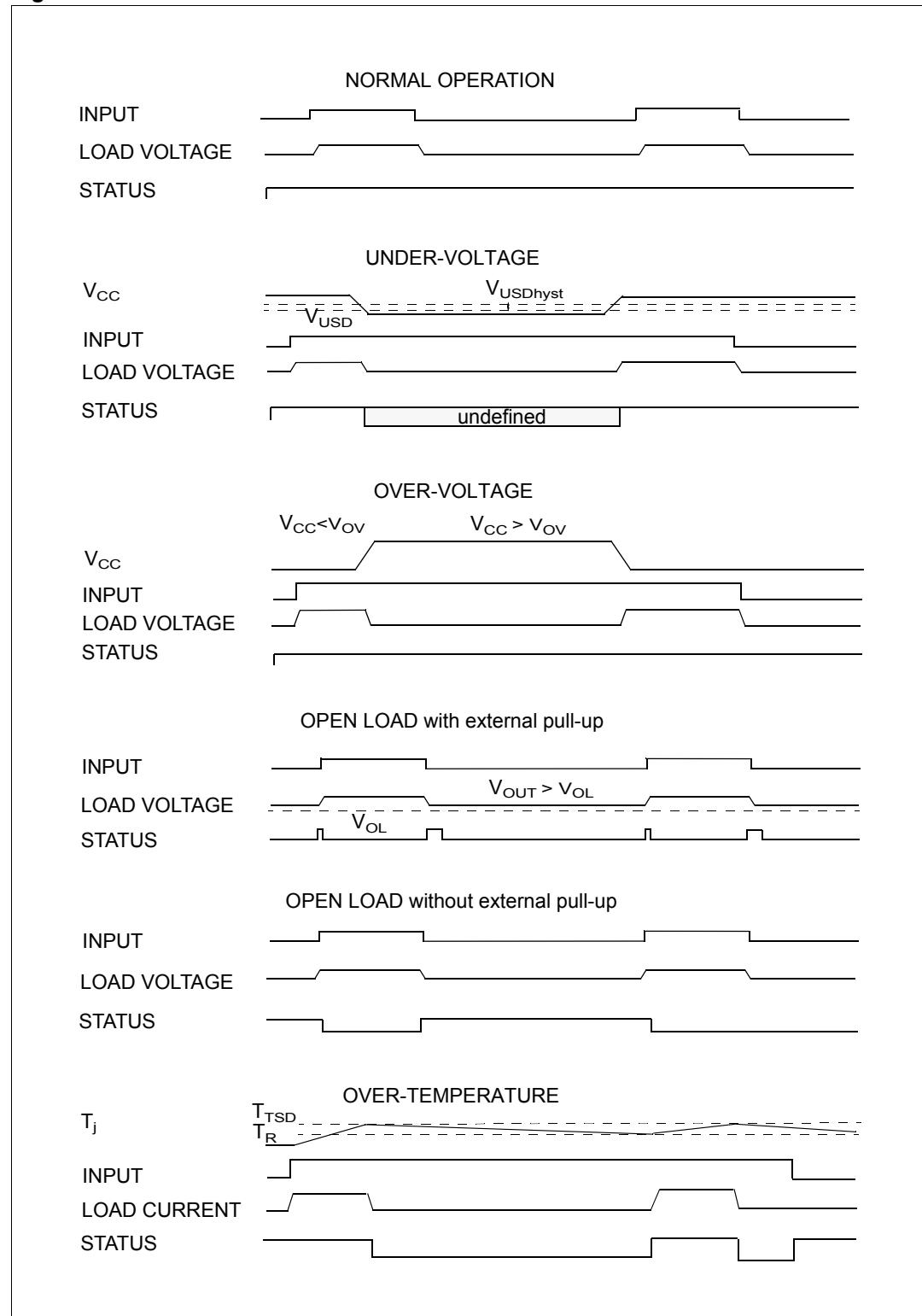
Conditions	Input	Output	Status
Normal operation	L	L	H
	H	H	H
Current limitation	L	L	H
	H	X	(T <sub>j</sub> < T <sub>TSD</sub> ) H
	H	X	(T <sub>j</sub> > T <sub>TSD</sub> ) L
Over-temperature	L	L	H
	H	L	L
Under-voltage	L	L	X
	H	L	X
Over-voltage	L	L	H
	H	L	H
Output voltage > V <sub>OL</sub>	L	H	L
	H	H	H
Output current < I <sub>OL</sub>	L	L	H
	H	H	L

**Table 13. Electrical transient requirements**

ISO T/R 7637/1 Test pulse	Test level				
	I	II	III	IV	Delays and impedance
1	- 25V <sup>(1)</sup>	- 50V <sup>(1)</sup>	- 75V <sup>(1)</sup>	- 100V <sup>(1)</sup>	2ms, 10Ω
2	+ 25V <sup>(1)</sup>	+ 50V <sup>(1)</sup>	+ 75V <sup>(1)</sup>	+ 100V <sup>(1)</sup>	0.2ms, 10Ω
3a	- 25V <sup>(1)</sup>	- 50V <sup>(1)</sup>	- 100V <sup>(1)</sup>	- 150V <sup>(1)</sup>	0.1μs, 50Ω
3b	+ 25V <sup>(1)</sup>	+ 50V <sup>(1)</sup>	+ 75V <sup>(1)</sup>	+ 100V <sup>(1)</sup>	0.1μs, 50Ω
4	- 4V <sup>(1)</sup>	- 5V <sup>(1)</sup>	- 6V <sup>(1)</sup>	- 7V <sup>(1)</sup>	100ms, 0.01Ω
5	+ 26.5V <sup>(1)</sup>	+ 46.5V <sup>(2)</sup>	+ 66.5V <sup>(2)</sup>	+ 86.5V <sup>(2)</sup>	400ms, 2Ω

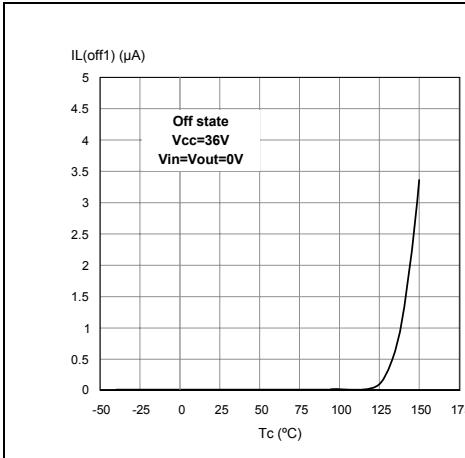
1. All functions of the device are performed as designed after exposure to disturbance.
2. One or more functions of the device is not performed as designed after exposure and cannot be returned to proper operation without replacing the device.

Figure 6. Waveforms

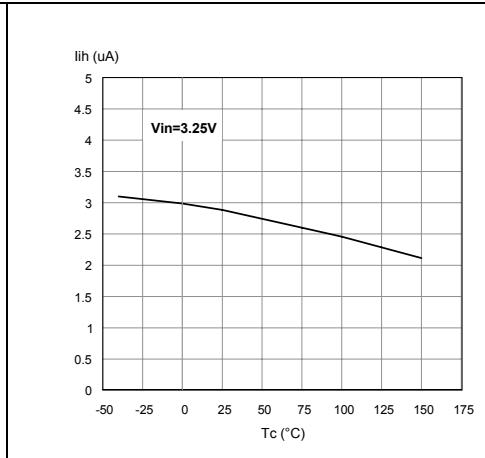


## 2.4 Electrical characteristics curves

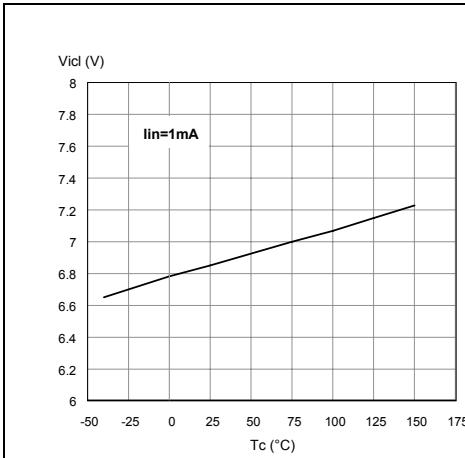
**Figure 7.** Off-state output current



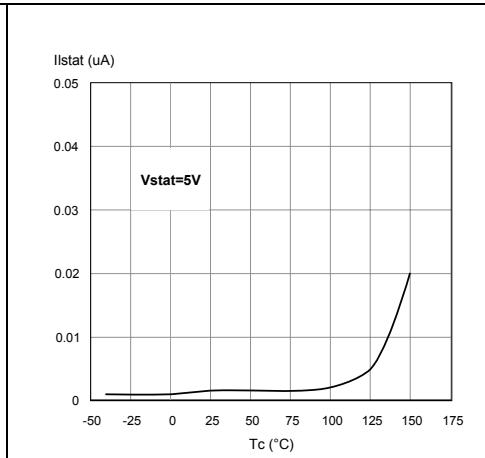
**Figure 8.** High level input current



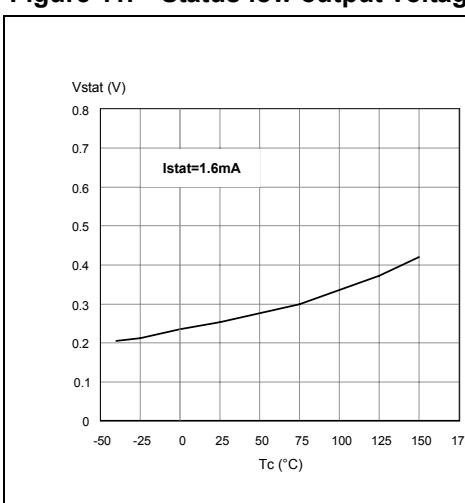
**Figure 9.** Input clamp voltage



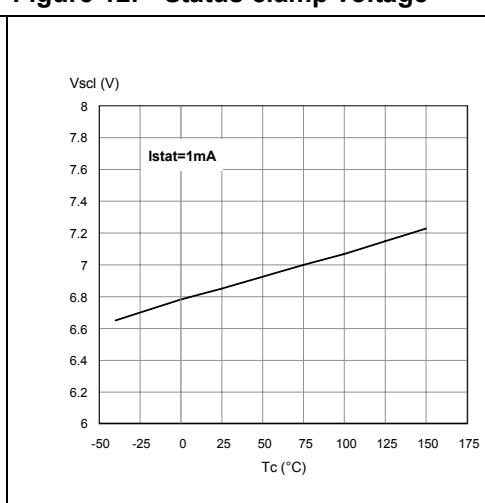
**Figure 10.** Status leakage current

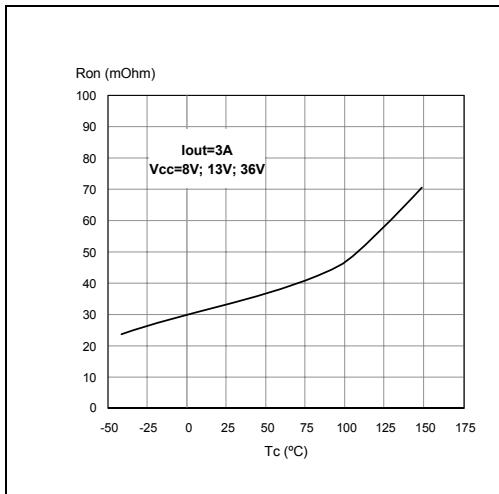
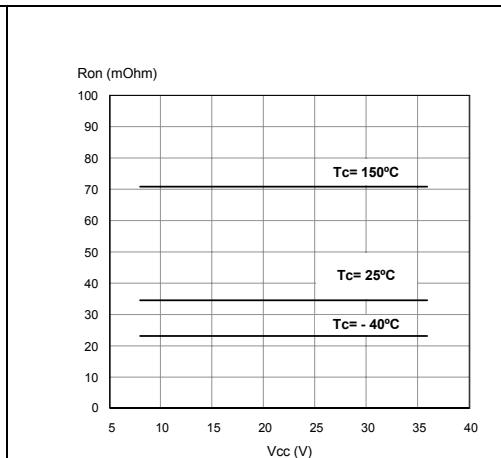
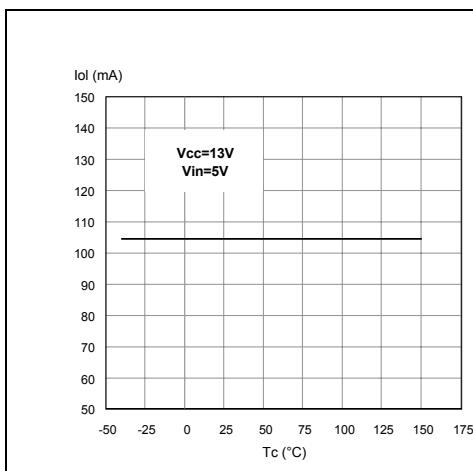
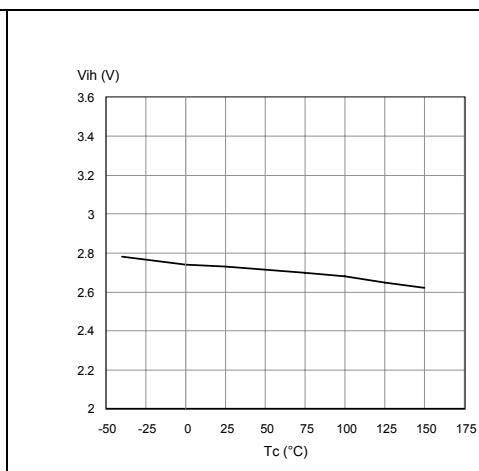
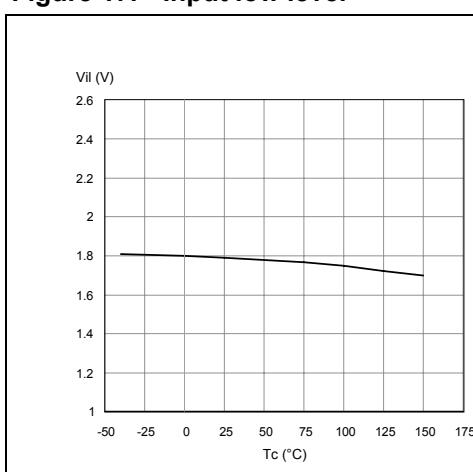
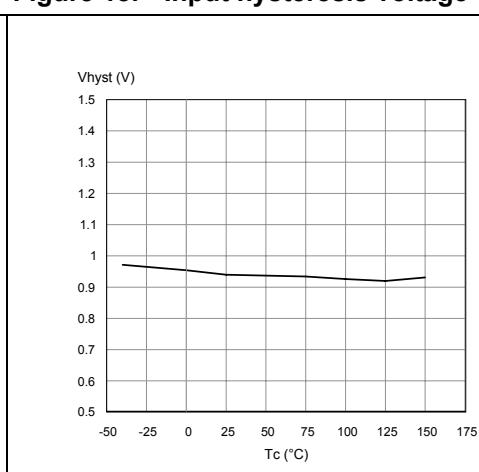


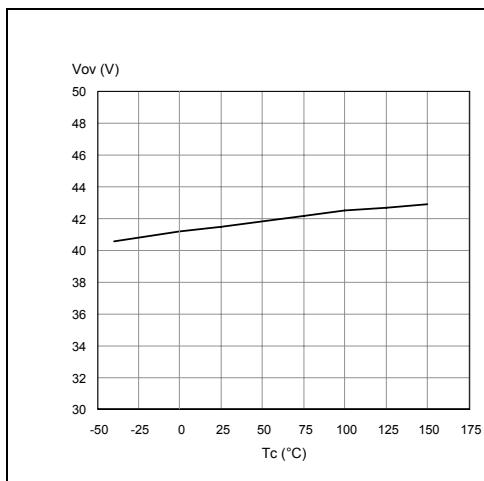
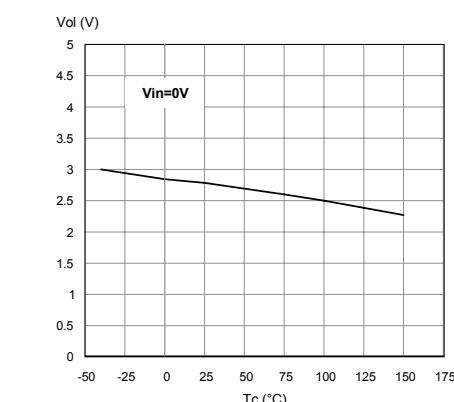
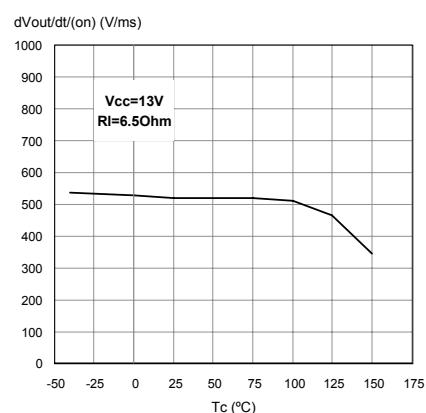
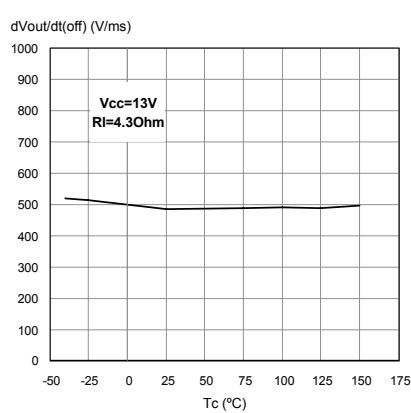
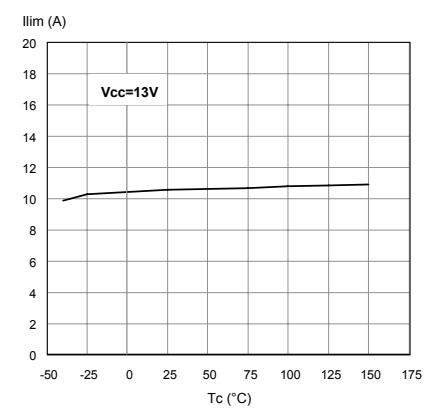
**Figure 11.** Status low output voltage



**Figure 12.** Status clamp voltage

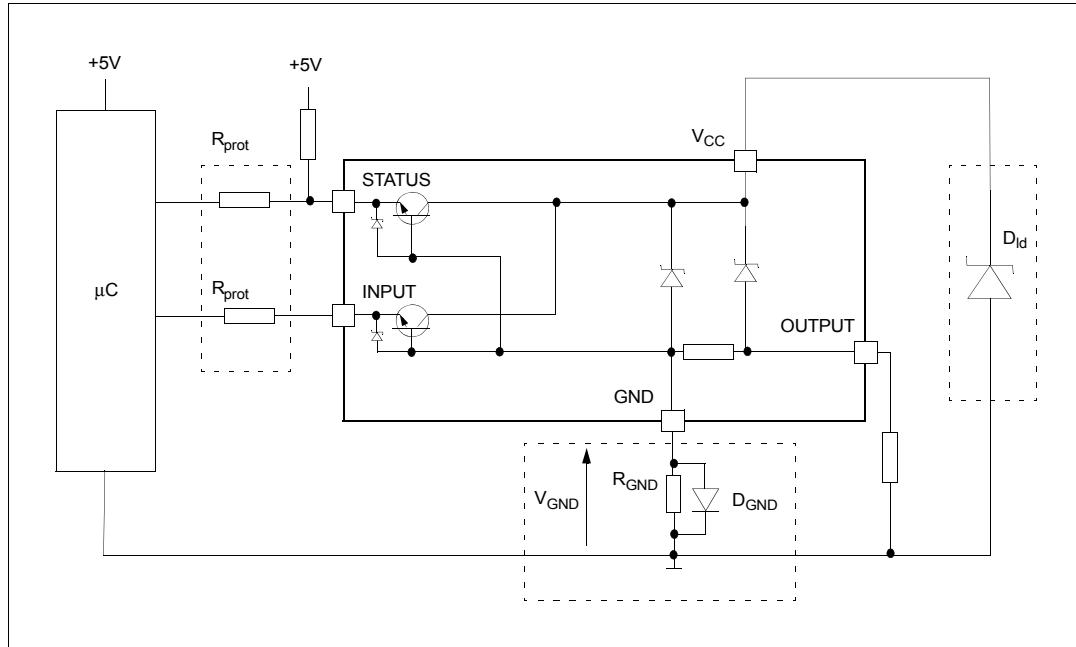


**Figure 13. On-state resistance Vs  $T_{case}$** **Figure 14. On-state resistance Vs  $V_{cc}$** **Figure 15. Open load on-state detection threshold****Figure 16. Input high level threshold****Figure 17. Input low level****Figure 18. Input hysteresis voltage**

**Figure 19. Over-voltage shutdown****Figure 20. Open load off-state voltage detection threshold****Figure 21. Turn-on voltage slope****Figure 22. Turn-off voltage slope****Figure 23.  $I_{lim}$  Vs  $T_{case}$** 

### 3 Application information

**Figure 24. Application schematic**



#### 3.1 GND protection network against reverse battery

##### 3.1.1 Solution 1: resistor in the ground line ( $R_{GND}$ only)

This can be used with any type of load.

The following is an indication on how to dimension the  $R_{GND}$  resistor.

1.  $R_{GND} \leq 600\text{mV} / (I_{S(on)\max})$ .
2.  $R_{GND} \geq (-V_{CC}) / (-I_{GND})$

where  $-I_{GND}$  is the DC reverse ground pin current and can be found in the absolute maximum rating section of the device datasheet.

Power Dissipation in  $R_{GND}$  (when  $V_{CC} < 0$ : during reverse battery situations) is:

$$P_D = (-V_{CC})^2 / R_{GND}$$

This resistor can be shared amongst several different HSDs. Please note that the value of this resistor should be calculated with formula (1) where  $I_{S(on)\max}$  becomes the sum of the maximum on-state currents of the different devices.

Please note that if the microprocessor ground is not shared by the device ground then the  $R_{GND}$  will produce a shift ( $I_{S(on)\max} * R_{GND}$ ) in the input thresholds and the status output values. This shift will vary depending on how many devices are ON in the case of several high-side drivers sharing the same  $R_{GND}$ .

If the calculated power dissipation leads to a large resistor or several devices have to share the same resistor then ST suggests to utilize Solution 2 (see below).

### 3.1.2 Solution 2: diode ( $D_{GND}$ ) in the ground line

A resistor ( $R_{GND} = 1\text{k}\Omega$ ) should be inserted in parallel to  $D_{GND}$  if the device drives an inductive load.

This small signal diode can be safely shared amongst several different HSDs. Also in this case, the presence of the ground network will produce a shift ( $\approx 600\text{mV}$ ) in the input threshold and in the status output values if the microprocessor ground is not common to the device ground. This shift will not vary if more than one HSD shares the same diode/resistor network.

Series resistor in INPUT and STATUS lines are also required to prevent that, during battery voltage transient, the current exceeds the absolute maximum rating.

Safest configuration for unused INPUT and STATUS pin is to leave them unconnected.

## 3.2 Load dump protection

$D_{ld}$  is necessary (Voltage Transient Suppressor) if the load dump peak voltage exceeds the  $V_{CC}$  max DC rating. The same applies if the device is subject to transients on the  $V_{CC}$  line that are greater than the ones shown in the ISO 7637-2: 2004(E) table.

## 3.3 MCU I/Os protection

If a ground protection network is used and negative transient are present on the  $V_{CC}$  line, the control pins will be pulled negative. ST suggests to insert a resistor ( $R_{prot}$ ) in line to prevent the  $\mu\text{C}$  I/Os pins to latch-up.

The value of these resistors is a compromise between the leakage current of  $\mu\text{C}$  and the current required by the HSD I/Os (Input levels compatibility) with the latch-up limit of  $\mu\text{C}$  I/Os.

$$-V_{CCpeak}/I_{latchup} \leq R_{prot} \leq (V_{OH\mu C} - V_{IH} - V_{GND}) / I_{IHmax}$$

Calculation example:

For  $V_{CCpeak} = -100\text{V}$  and  $I_{latchup} \geq 20\text{mA}$ ;  $V_{OH\mu C} \geq 4.5\text{V}$

$$5\text{k}\Omega \leq R_{prot} \leq 65\text{k}\Omega$$

Recommended values:  $R_{prot} = 10\text{k}\Omega$ .

## 3.4 Open load detection in off-state

Off-state open load detection requires an external pull-up resistor ( $R_{PU}$ ) connected between OUTPUT pin and a positive supply voltage ( $V_{PU}$ ) like the +5V line used to supply the microprocessor.

The external resistor has to be selected according to the following requirements:

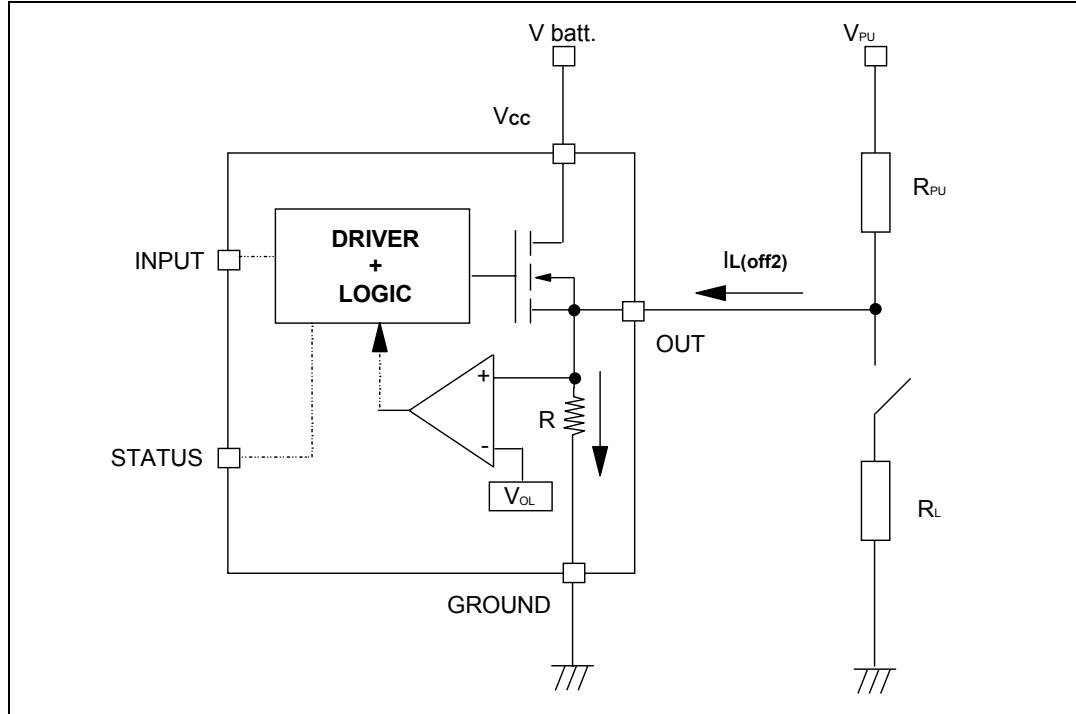
1. no false open load indication when load is connected: in this case we have to avoid  $V_{OUT}$  to be higher than  $V_{OLmin}$ ; this results in the following condition  

$$V_{OUT} = (V_{PU} / (R_L + R_{PU})) R_L < V_{OLmin}$$
2. no misdetection when load is disconnected: in this case the  $V_{OUT}$  has to be higher than  $V_{OLmax}$ ; this results in the following condition  $R_{PU} < (V_{PU} - V_{OLmax}) / I_{L(off2)}$ .

Because  $I_{S(OFF)}$  may significantly increase if  $V_{out}$  is pulled high (up to several mA), the pull-up resistor  $R_{PU}$  should be connected to a supply that is switched off when the module is in standby.

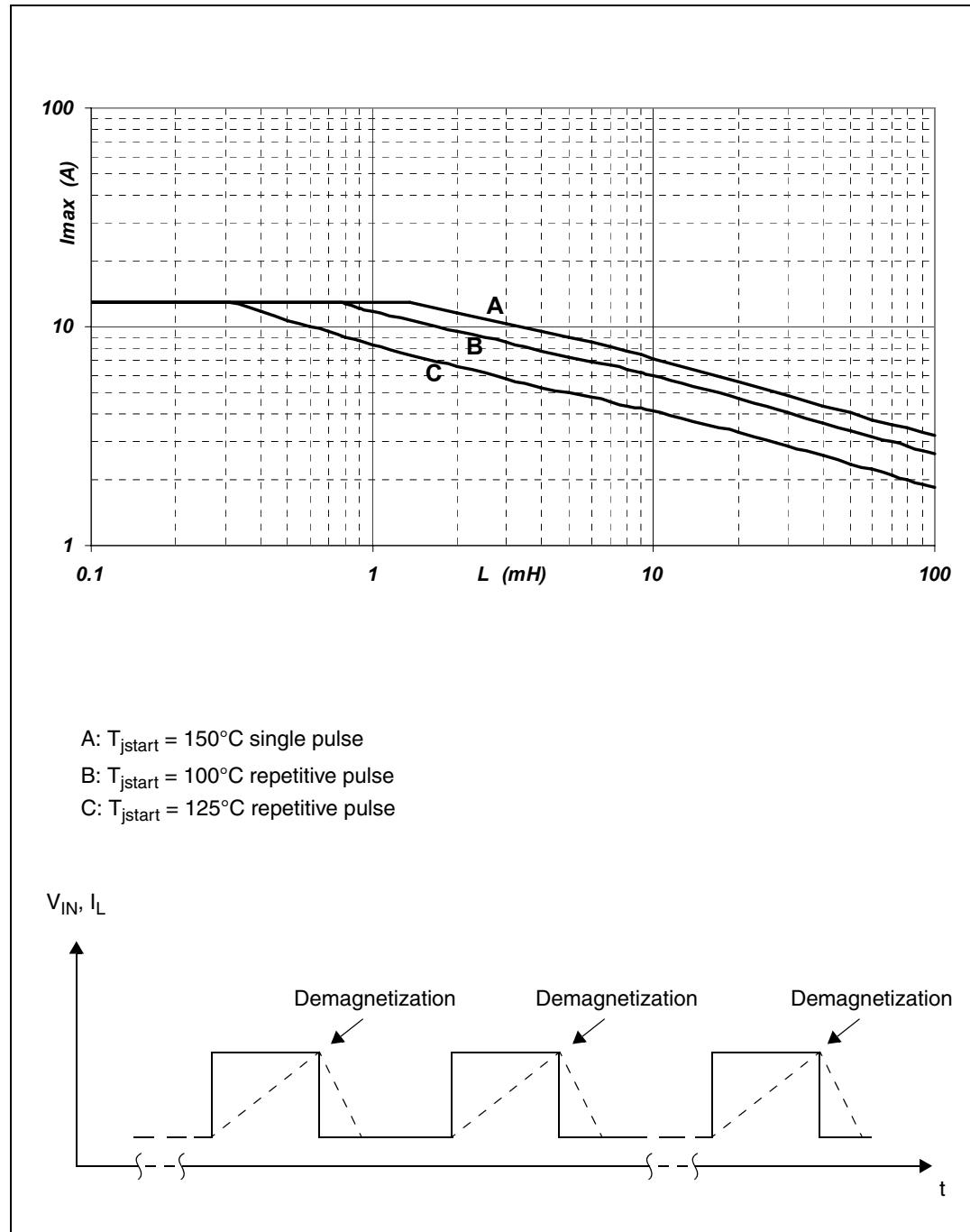
The values of  $V_{OLmin}$ ,  $V_{OLmax}$  and  $I_{L(off2)}$  are available in the electrical characteristics section.

**Figure 25. Open load detection in off-state**



### 3.5 PowerSO-10, P<sup>2</sup>PAK, PPAK, PENTAWATT maximum demagnetization energy ( $V_{CC} = 13.5V$ )

**Figure 26. PowerSO-10, P<sup>2</sup>PAK, PPAK, PENTAWATT maximum turn-off current versus inductance**



Note:

Values are generated with  $R_L = 0 \Omega$ . In case of repetitive pulses,  $T_{jstart}$  (at beginning of each demagnetization) of every pulse must not exceed the temperature specified above for curves A and B.

## 4 Package and PCB thermal data

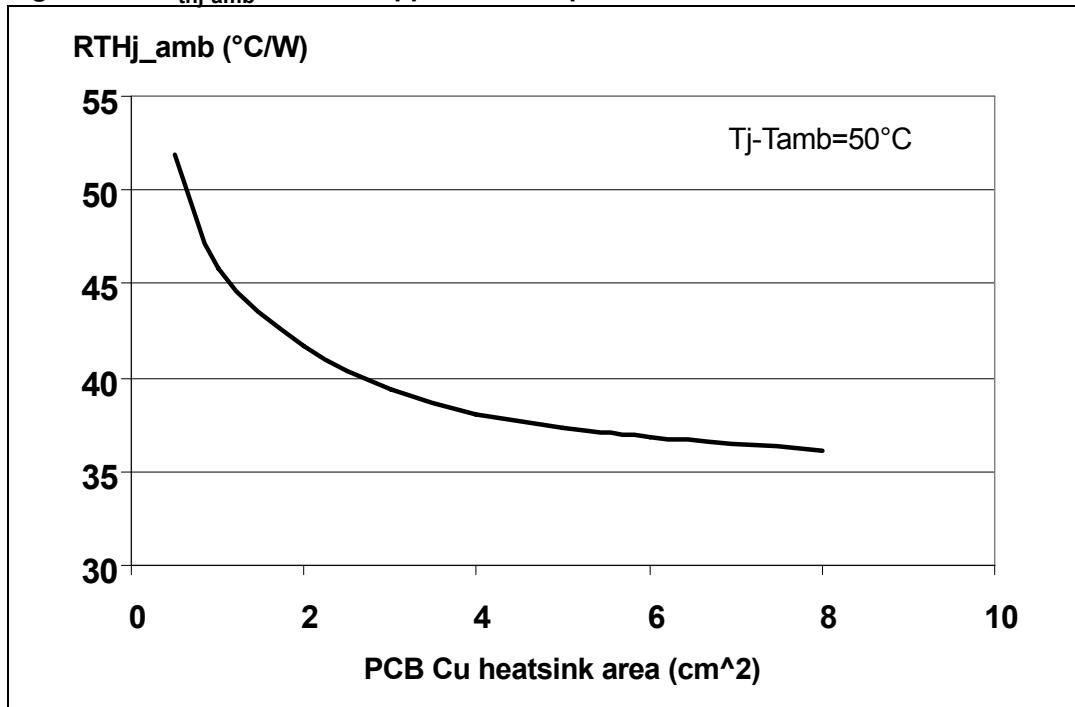
### 4.1 P<sup>2</sup>PAK thermal data

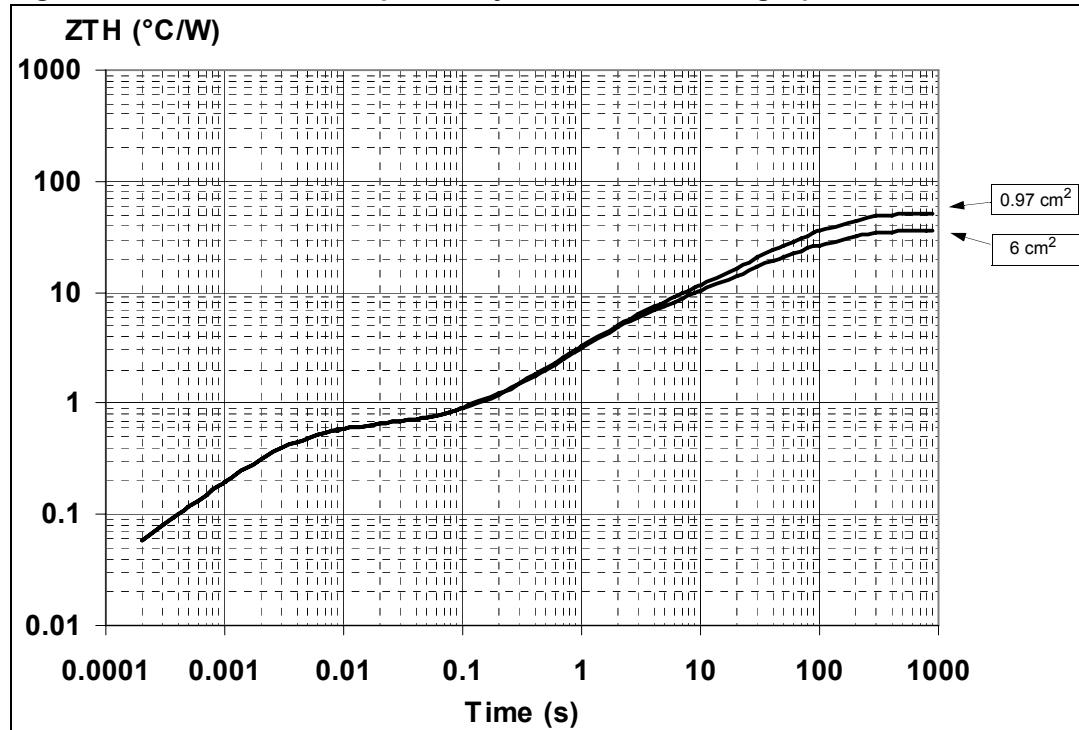
Figure 27. PC board



Note: Layout condition of  $R_{th}$  and  $Z_{th}$  measurements (PCB FR4 area = 60 mm x 60 mm, PCB thickness = 2 mm, Cu thickness = 35  $\mu$ m, Copper areas: 0.97 cm<sup>2</sup>, 8 cm<sup>2</sup>).

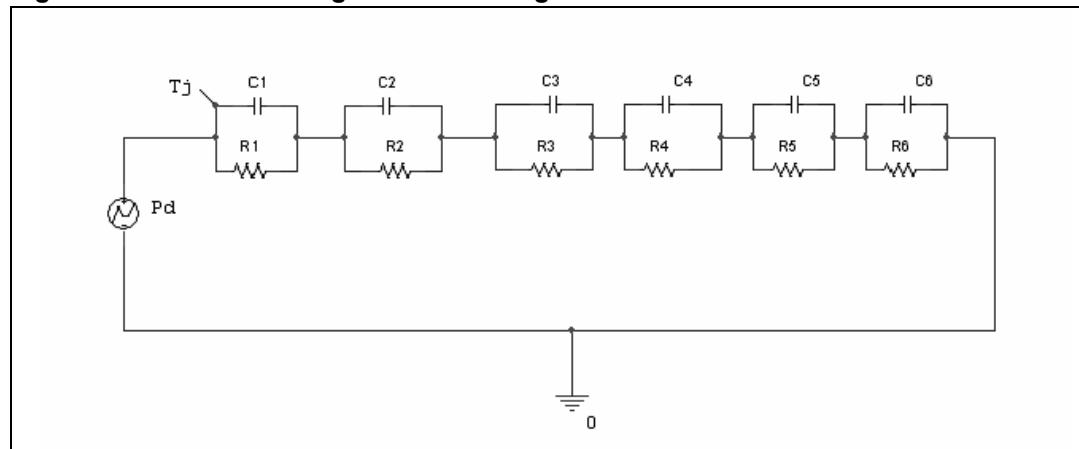
Figure 28.  $R_{thj\_amb}$  vs PCB copper area in open box free air condition



**Figure 29. P<sup>2</sup>PAK thermal impedance junction ambient single pulse****Equation 1: pulse calculation formula**

$$Z_{TH\delta} = R_{TH} \cdot \delta + Z_{THtp}(1 - \delta)$$

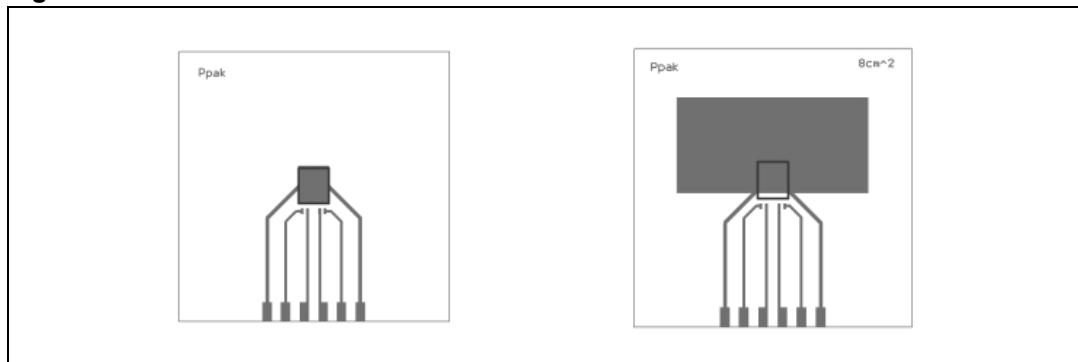
where  $\delta = t_p/T$

**Figure 30. Thermal fitting model of a single channel**

**Table 14. Thermal parameter**

<b>Area/island (cm<sup>2</sup>)</b>	<b>0.97</b>	<b>6</b>
R1 (°C/W)	0.04	
R2 (°C/W)	0.25	
R3 (°C/W)	0.3	
R4 (°C/W)	4	
R5 (°C/W)	9	
R6 (°C/W)	37	22
C1 (W·s/°C)	0.0008	
C2 (W·s/°C)	0.007	
C3 (W·s/°C)	0.015	
C4 (W·s/°C)	0.4	
C5 (W·s/°C)	2	
C6 (W·s/°C)	3	5

## 4.2 PPAK thermal data

**Figure 31. PC board**

Note:

Layout condition of  $R_{th}$  and  $Z_{th}$  measurements (PCB FR4 area = 60 mm x 60 mm, PCB thickness = 2 mm, Cu thickness=35  $\mu$ m , Copper areas: 0.44 cm<sup>2</sup>, 8 cm<sup>2</sup>).

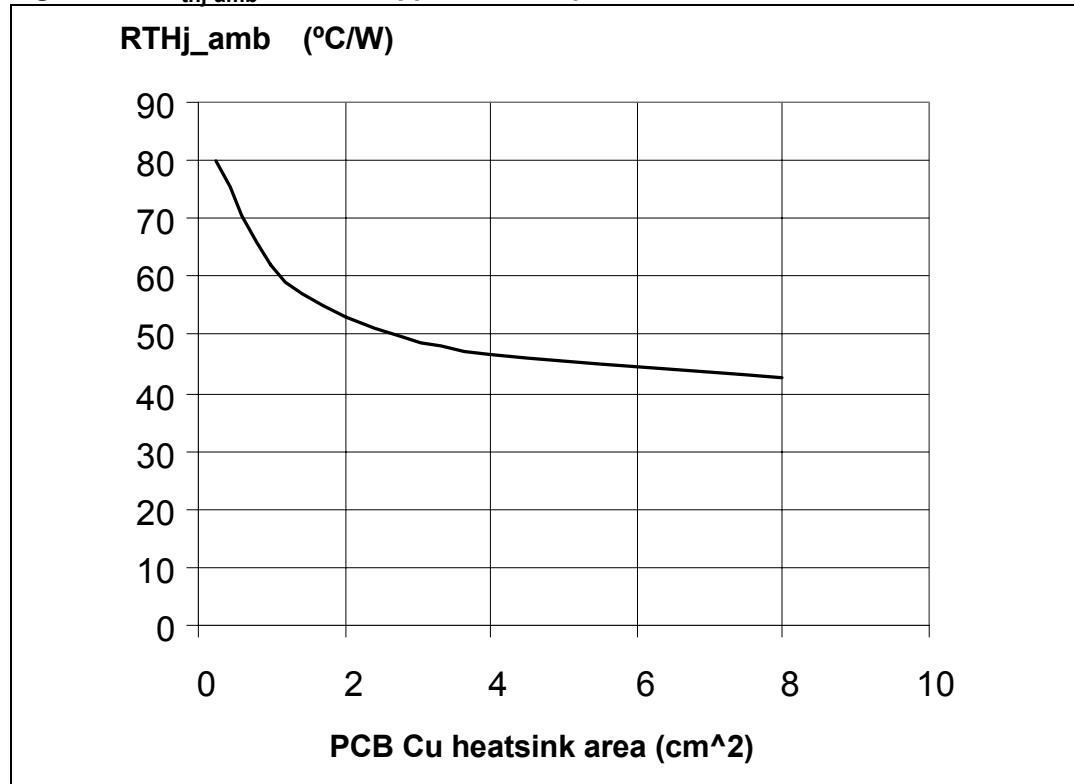
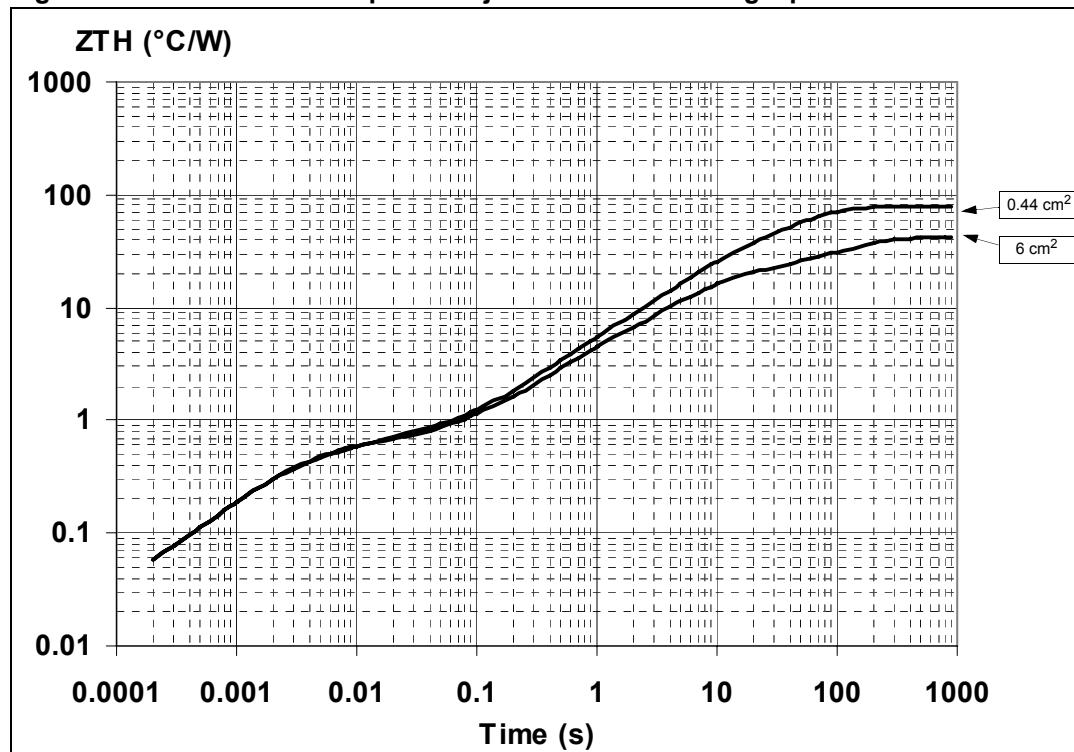
Figure 32.  $R_{thj\text{-amb}}$  vs PCB copper area in open box free air condition

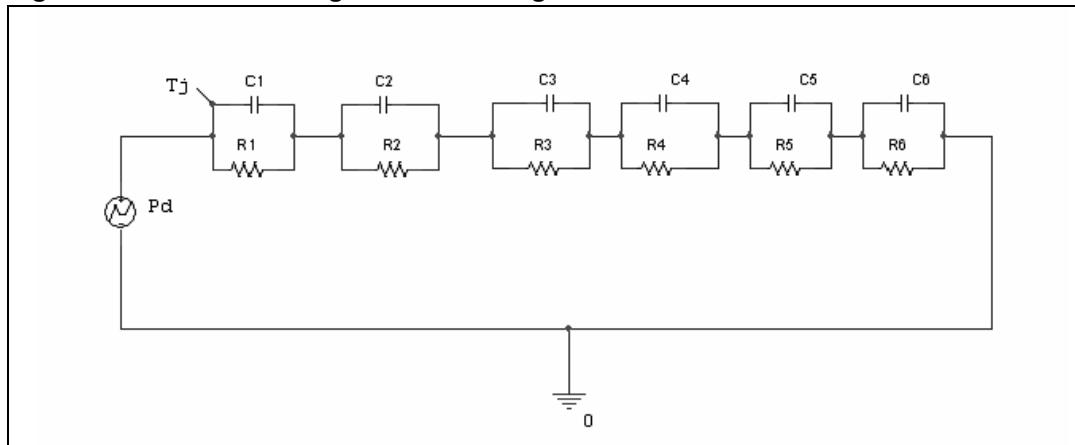
Figure 33. PPAK thermal impedance junction ambient single pulse



**Equation 2: pulse calculation formula**

$$Z_{TH\delta} = R_{TH} \cdot \delta + Z_{THtp}(1 - \delta)$$

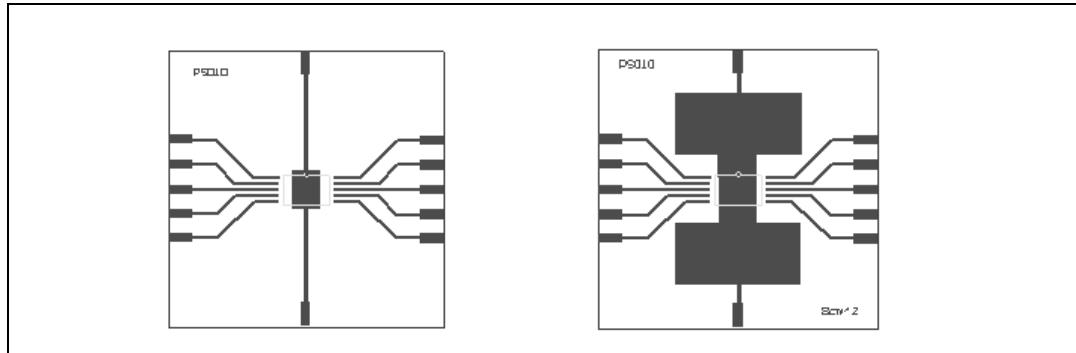
where  $\delta = t_p/T$

**Figure 34. Thermal fitting model of a single channel****Table 15. Thermal parameter**

Area/island (cm <sup>2</sup> )	0.44	6
R1 (°C/W)	0.04	
R2 (°C/W)	0.25	
R3 (°C/W)	0.3	
R4 (°C/W)	2	
R5 (°C/W)	15	
R6 (°C/W)	61	24
C1 (W·s/°C)	0.0008	
C2 (W·s/°C)	0.007	
C3 (W·s/°C)	0.02	
C4 (W·s/°C)	0.3	
C5 (W·s/°C)	0.45	
C6 (W·s/°C)	0.8	5

### 4.3 PowerSO-10 thermal data

Figure 35. PowerSO-10 PC board



Note:

Layout condition of  $R_{th}$  and  $Z_{th}$  measurements (PCB FR4 area = 58 mm x 58 mm, PCB thickness = 2 mm, Cu thickness = 35  $\mu$ m, Copper areas: from minimum pad lay-out to 8  $\text{cm}^2$ ).

Figure 36.  $R_{thj\text{-amb}}$  vs PCB copper area in open box free air condition

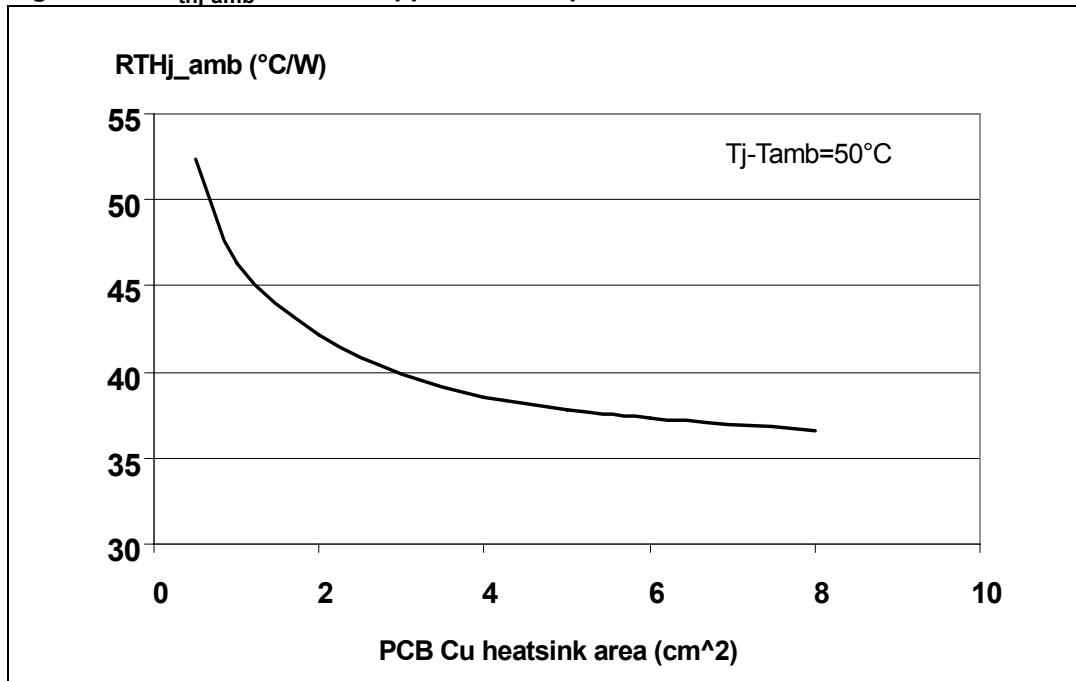
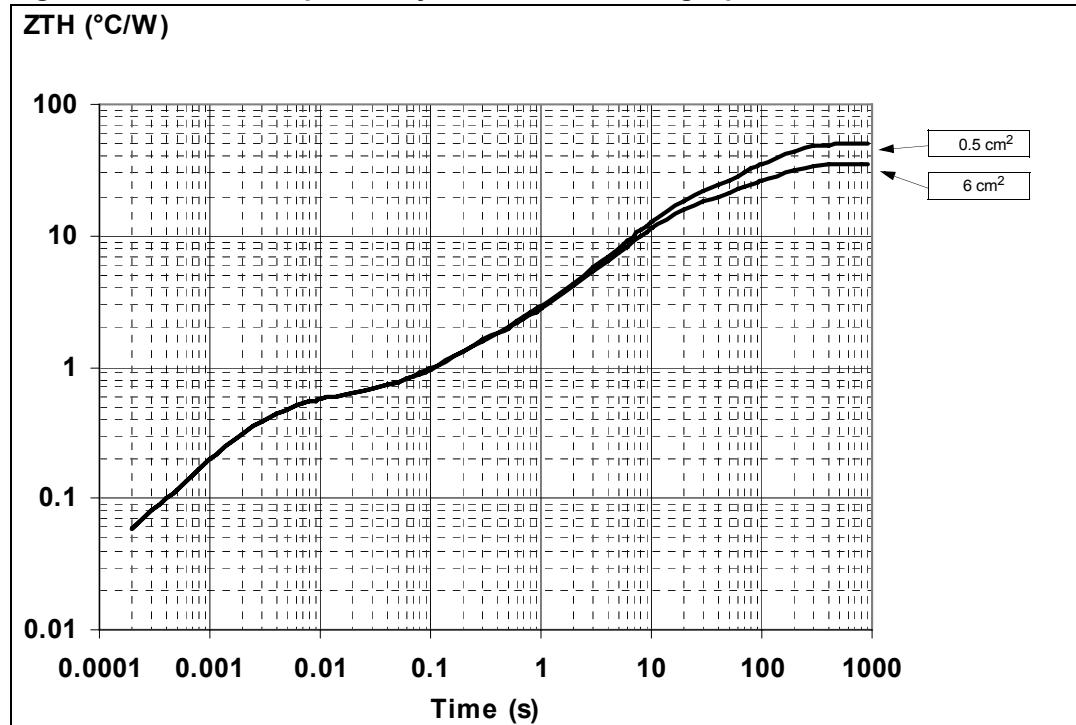


Figure 37. Thermal impedance junction ambient single pulse

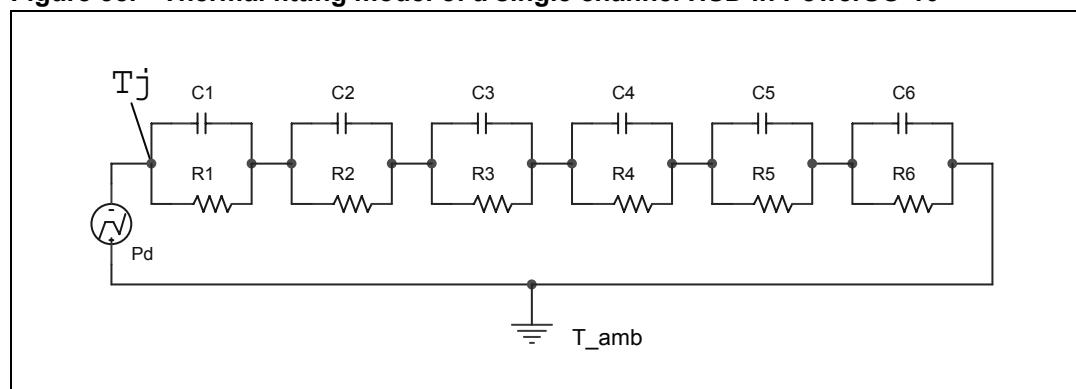


Equation 3: pulse calculation formula

$$Z_{TH\delta} = R_{TH} \cdot \delta + Z_{THtp}(1 - \delta)$$

where  $\delta = t_p/T$

Figure 38. Thermal fitting model of a single channel HSD in PowerSO-10



**Table 16. Thermal parameters**

Area / island (cm <sup>2</sup> )	Footprint	6
R1 (°C/W)	0.04	
R2 (°C/W)	0.25	
R3 (°C/W)	0.25	
R4 (°C/W)	0.8	
R5 (°C/W)	12	
R6 (°C/W)	37	22
C1 (W.s/°C)	0.0008	
C2 (W.s/°C)	7E-03	
C3 (W.s/°C)	0.015	
C4 (W.s/°C)	0.3	
C5 (W.s/°C)	0.75	
C6 (W.s/°C)	3	5

## 5 Package and packing information

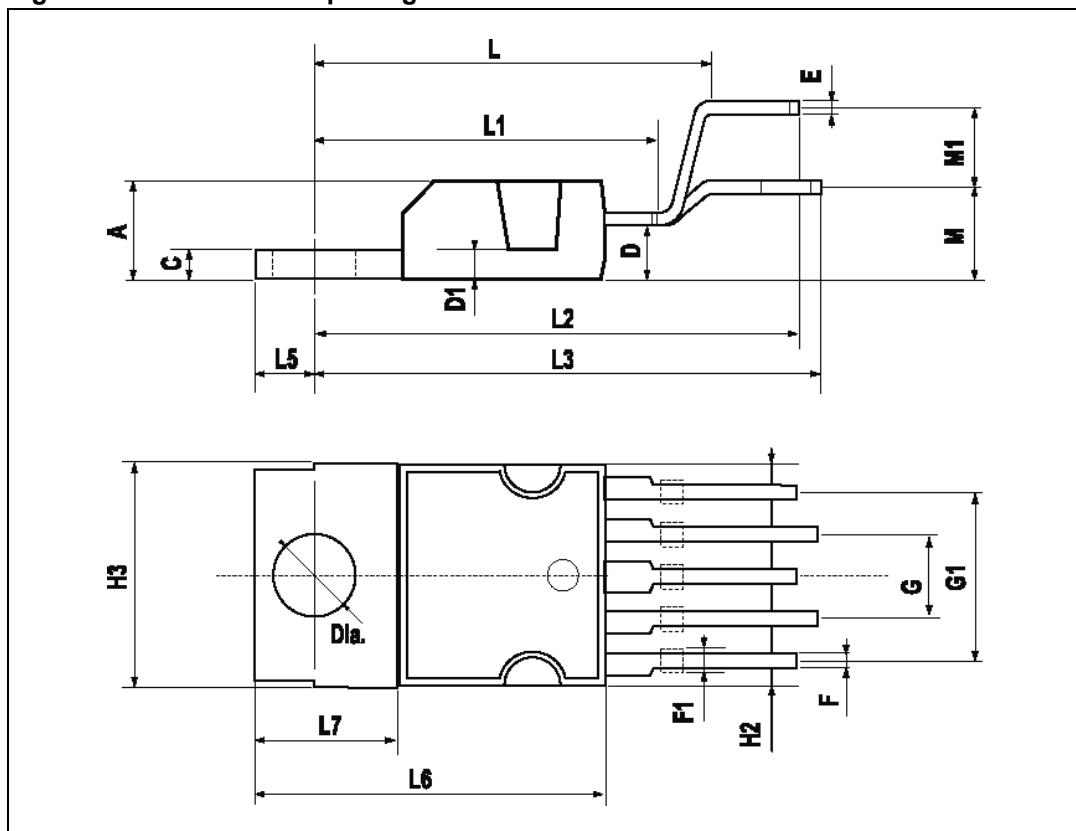
### 5.1 ECOPACK®

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### 5.2 PENTAWATT mechanical data

Figure 39. PENTAWATT package dimensions

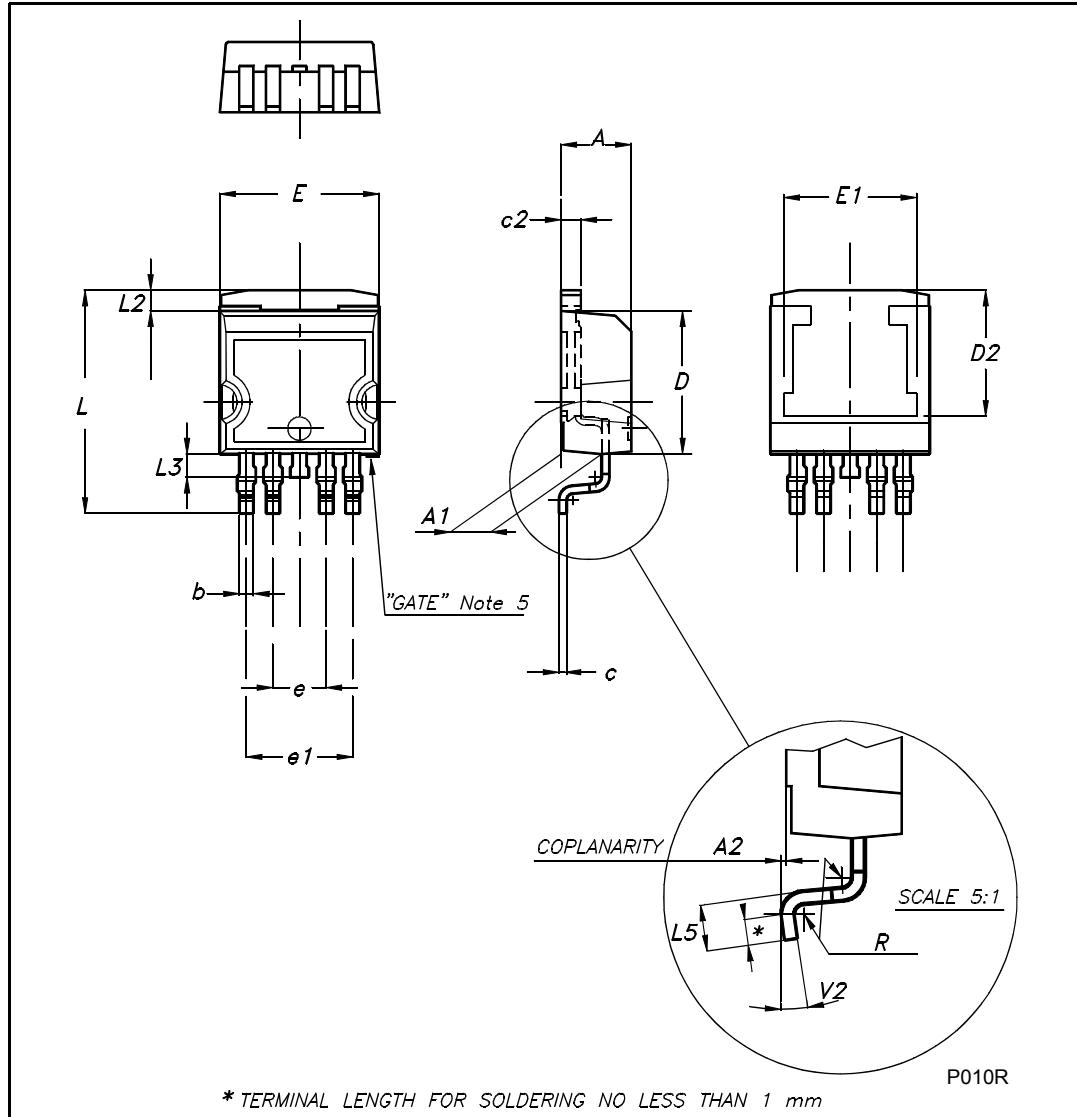


**Table 17. PENTAWATT mechanical data**

Dim.	mm		
	Min.	Typ.	Max.
A			4.8
C			1.37
D	2.4		2.8
D1	1.2		1.35
E	0.35		0.55
F	0.8		1.05
F1	1		1.4
G	3.2	3.4	3.6
G1	6.6	6.8	7
H2			10.4
H3	10.05		10.4
L		17.85	
L1		15.75	
L2		21.4	
L3		22.5	
L5	2.6		3
L6	15.1		15.8
L7	6		6.6
M		4.5	
M1		4	
Diam.	3.65		3.85

### 5.3 P<sup>2</sup>PAK mechanical data

Figure 40. P<sup>2</sup>PAK package dimensions



**Table 18. P<sup>2</sup>PAK mechanical data**

Dim.	mm		
	Min.	Typ.	Max.
A	4.30		4.80
A1	2.40		2.80
A2	0.03		0.23
b	0.80		1.05
c	0.45		0.60
c2	1.17		1.37
D	8.95		9.35
D2		8.00	
E	10.00		10.40
E1		8.50	
e	3.20		3.60
e1	6.60		7.00
L	13.70		14.50
L2	1.25		1.40
L3	0.90		1.70
L5	1.55		2.40
R		0.40	
V2	0°		8°
Package weight	1.40 Gr (typ)		

## 5.4 PPAK mechanical data

Figure 41. PPAK package dimensions

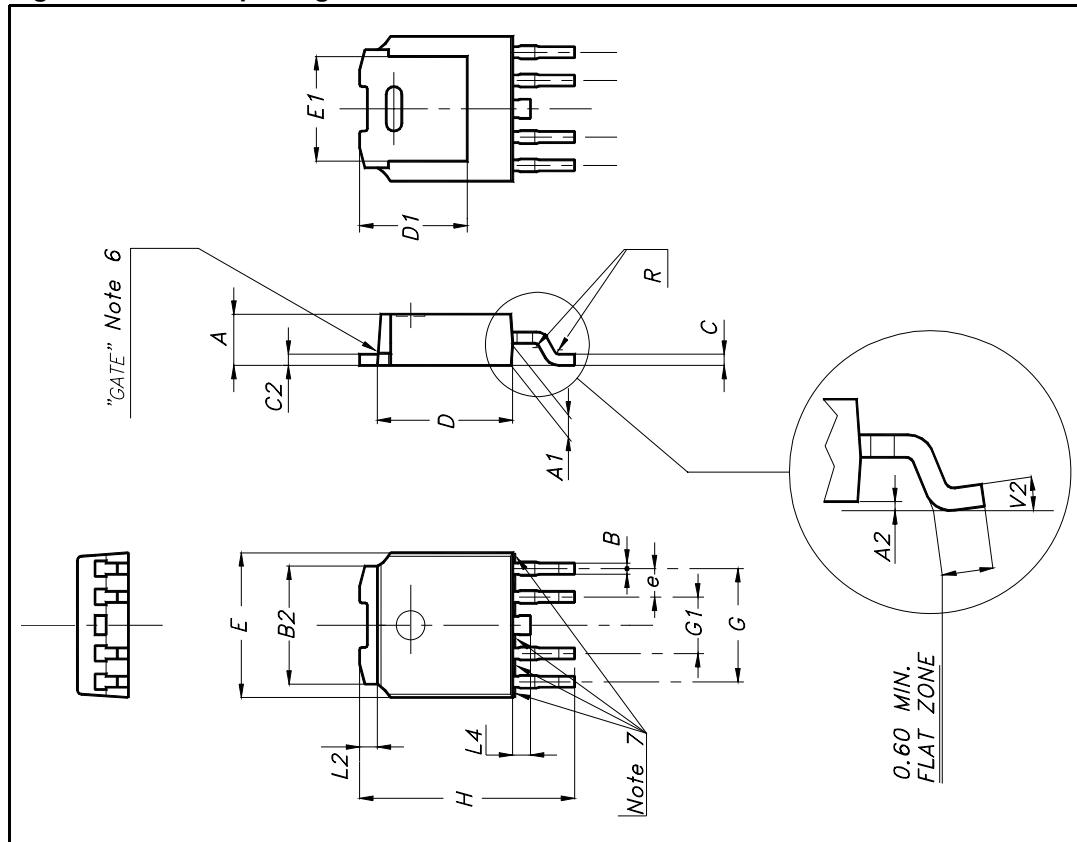


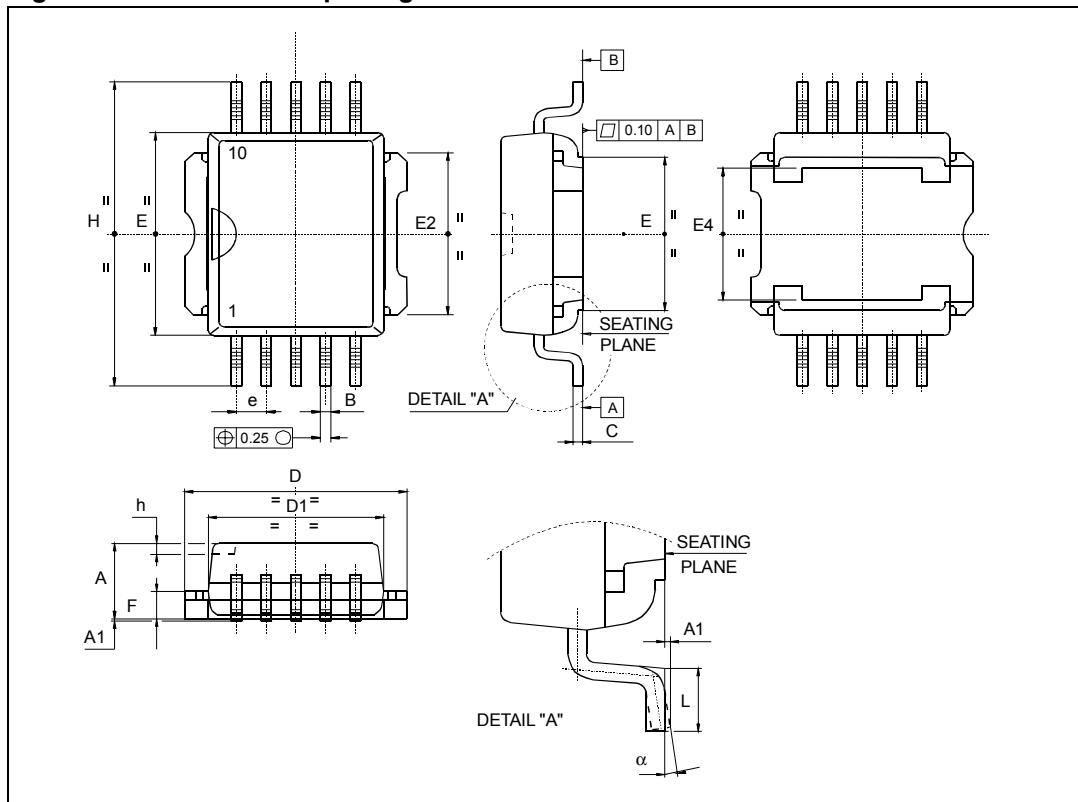
Table 19. PPAK mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	2.20		2.40
A1	0.90		1.10
A2	0.03		0.23
B	0.40		0.60
B2	5.20		5.40
C	0.45		0.60
C2	0.48		0.60
D1		5.1	
D	6.00		6.20
E	6.40		6.60

**Table 19. PPAK mechanical data (continued)**

Dim.	mm		
	Min.	Typ.	Max.
E1		4.7	
e		1.27	
G	4.90		5.25
G1	2.38		2.70
H	9.35		10.10
L2		0.8	1.00
L4	0.60		1.00
R		0.2	
V2	0°		8°
Package weight	Gr. 0.3		

## 5.5 PowerSO-10 mechanical data

**Figure 42. PowerSO-10 package dimensions**

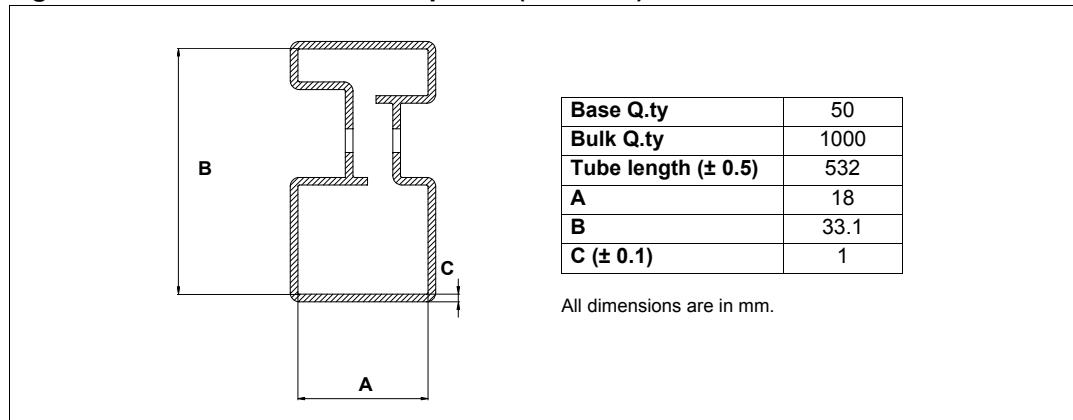
**Table 20. PowerSO-10 mechanical data**

Dim.	mm		
	Min.	Typ.	Max.
A	3.35		3.65
A <sup>(1)</sup>	3.4		3.6
A1	0		0.10
B	0.40		0.60
B <sup>(1)</sup>	0.37		0.53
C	0.35		0.55
C <sup>(1)</sup>	0.23		0.32
D	9.40		9.60
D1	7.40		7.60
E	9.30		9.50
E2	7.20		7.60
E2 <sup>(1)</sup>	7.30		7.50
E4	5.90		6.10
E4 <sup>(1)</sup>	5.90		6.30
e		1.27	
F	1.25		1.35
F <sup>(1)</sup>	1.20		1.40
H	13.80		14.40
H <sup>(1)</sup>	13.85		14.35
h		0.50	
L	1.20		1.80
L <sup>(1)</sup>	0.80		1.10
α	0°		8°
α <sup>(1)</sup>	2°		8°

1. Muar only POA P013P.

## 5.6 PENTAWATT packing information

Figure 43. PENTAWATT tube shipment (no suffix)



## 5.7 P<sup>2</sup>PAK packing information

Figure 44. P<sup>2</sup>PAK tube shipment (no suffix)

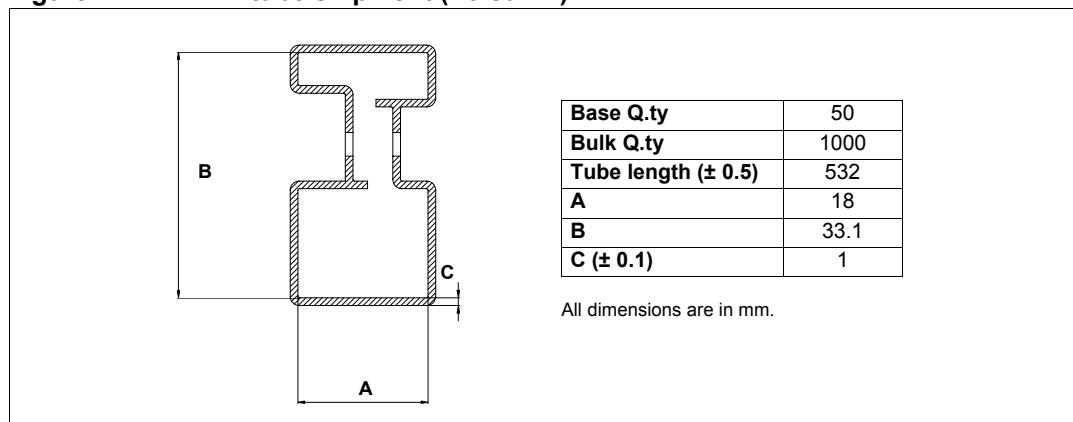
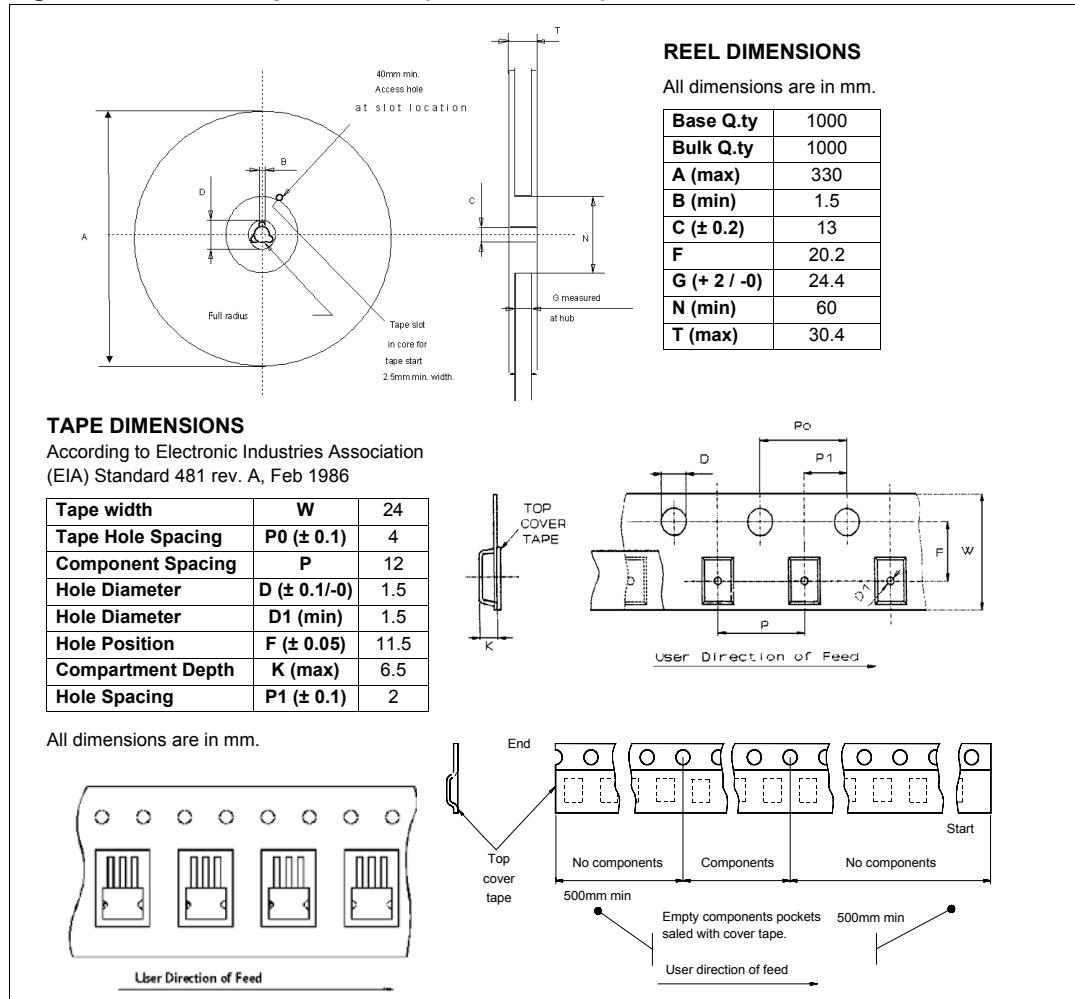
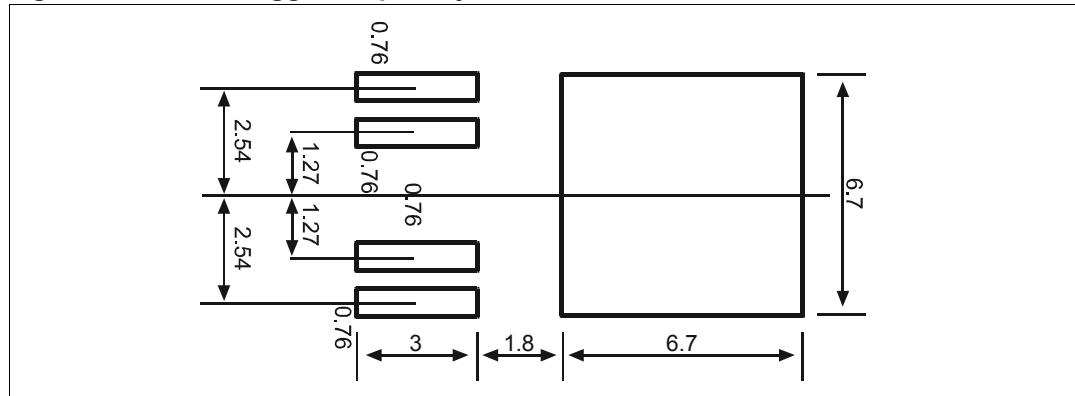


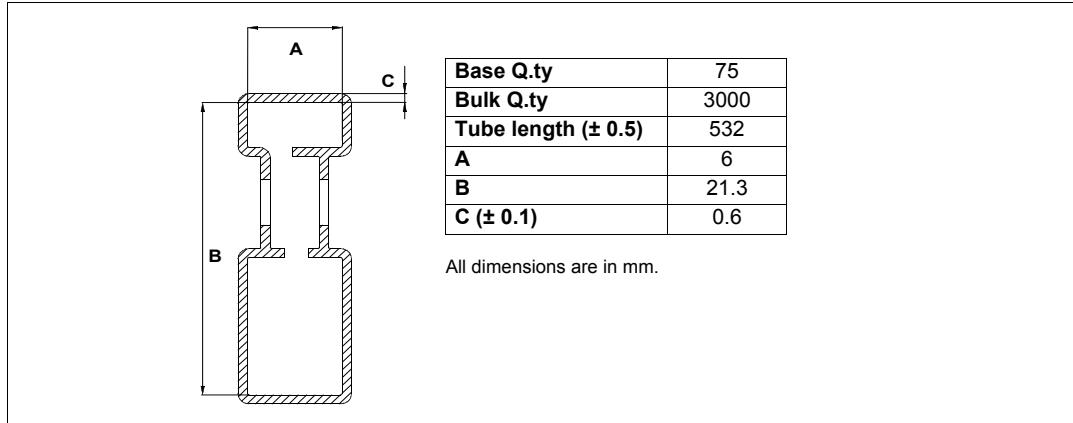
Figure 45. P<sup>2</sup>PAK tape and reel (suffix "13TR")

## 5.8 PPAK packing information

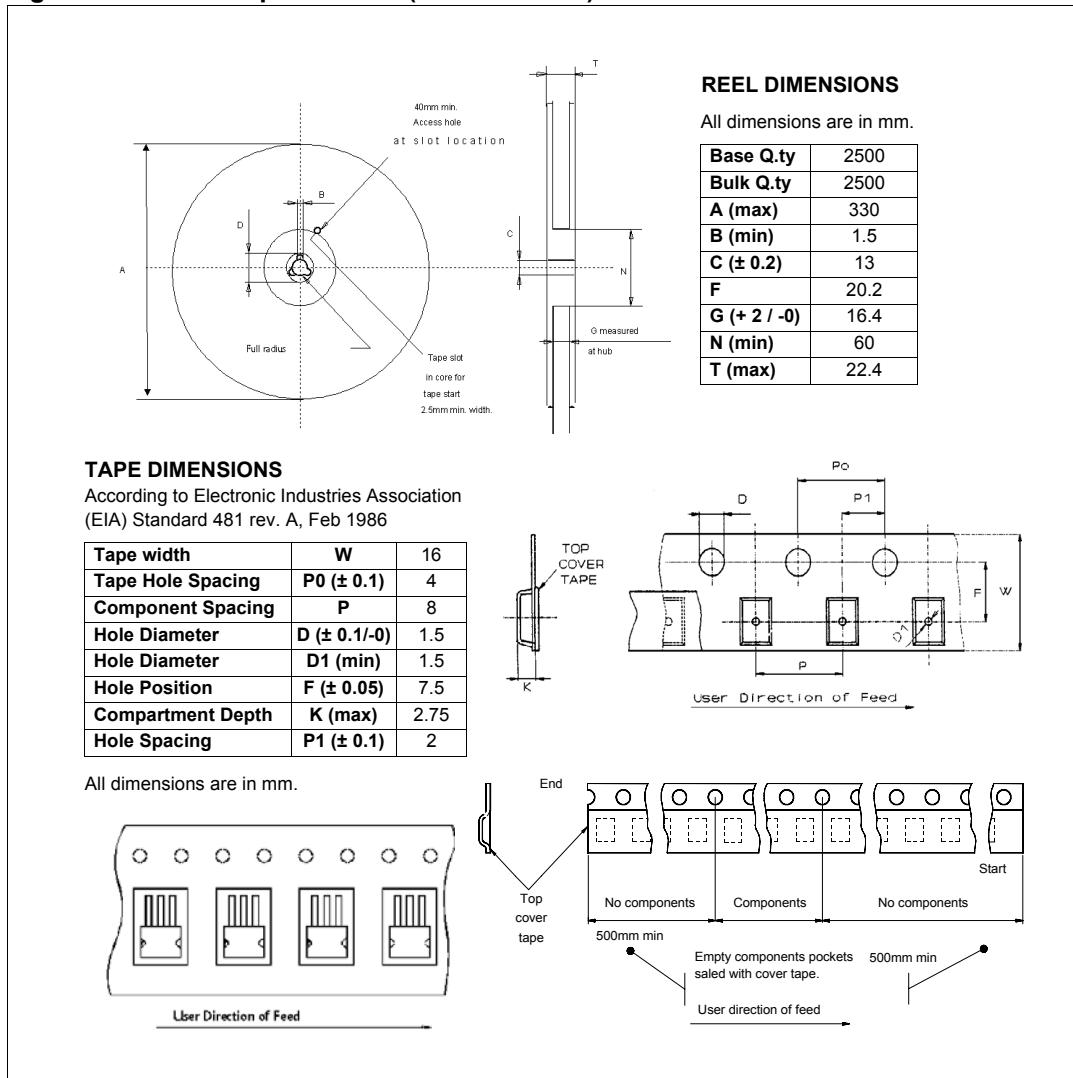
Figure 46. PPAK suggested pad layout



**Figure 47. PPAK tube shipment (no suffix)**

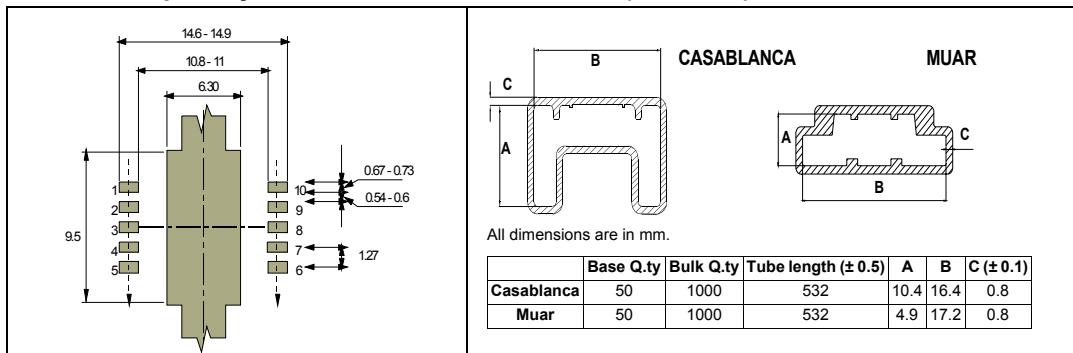


**Figure 48.** PPAK tape and reel (suffix “13TR”)

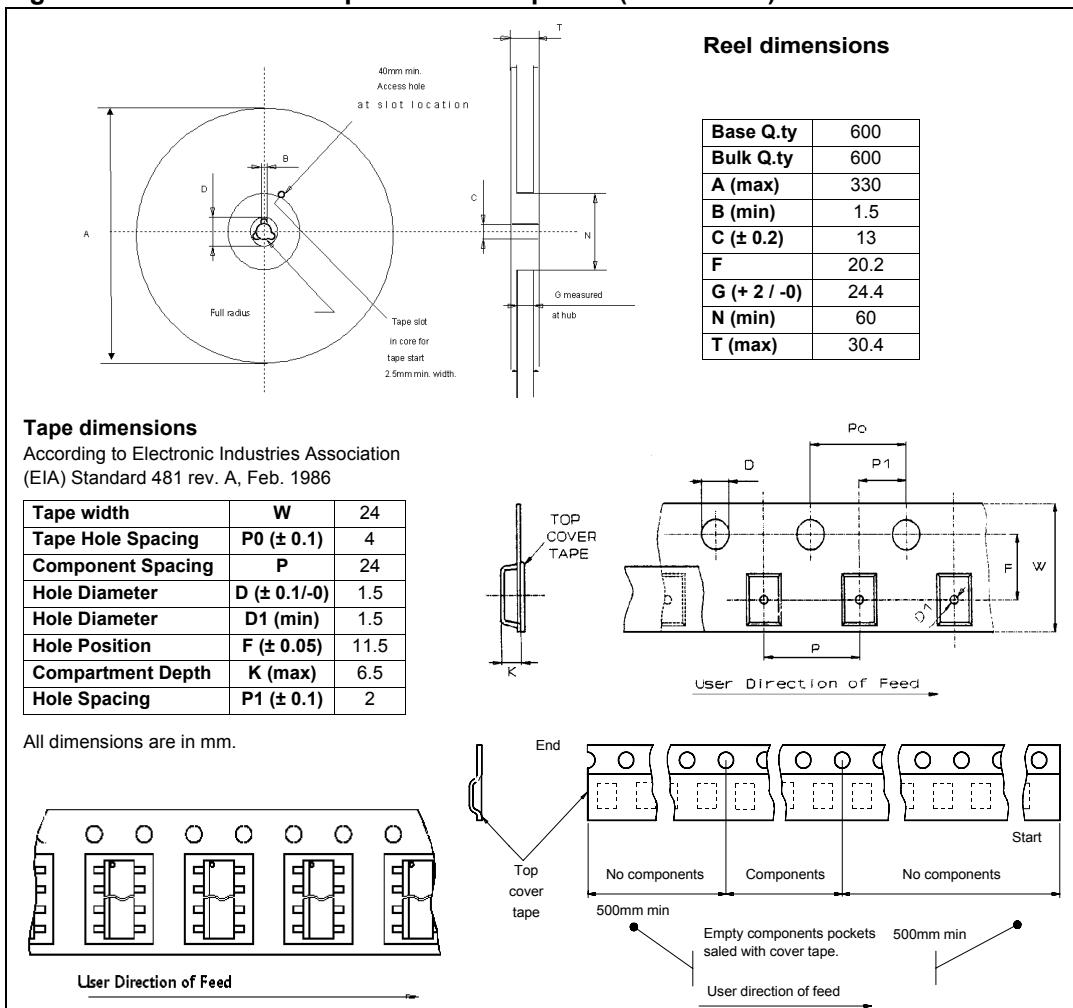


## 5.9 PowerSO-10 packing information

**Figure 49.** PowerSO-10 suggested pad layout



**Figure 50.** PowerSO-10 tube shipment (no suffix)



## 6 Revision history

**Table 21. Document revision history**

Date	Revision	Changes
07-Jul-2004	1	Initial release.
03-May-2006	2	Minor changes Current and voltage convention update (page 2). Configuration diagram (top view) and suggested connections for unused and n.c. pins insertion (page 2). 6 cm <sup>2</sup> Cu condition insertion in thermal data table (page 3). $V_{CC}$ - output diode section update (page 4). Revision history table insertion (page 34). Disclaimers update (page 35).
17-Dec-2008	3	Document reformatted and restructured. Added content, list of figures and tables. Added <b>ECOPACK® packages</b> information. Updated <a href="#">Figure 45.: P<sup>2</sup>PAK tape and reel (suffix "13TR")</a> : – changed component spacing (P) in tape dimensions table from 16 mm to 12 mm.
31-Mar-2010	4	Updated document template. Updated features list. Removed SO-16L package into the document: – Updated <a href="#">Table 1: Device summary</a> – Updated <a href="#">Table 3: Absolute maximum ratings</a> – Updated <a href="#">Table 4: Thermal data</a> – Updated <a href="#">Section 3.5: PowerSO-10, P<sup>2</sup>PAK, PPAK, PENTAWATT maximum demagnetization energy (VCC = 13.5V)</a> – Updated <a href="#">Section 4: Package and PCB thermal data</a> – Updated <a href="#">Section 5: Package and packing information</a>

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